



XT25F32B-S

Quad IO Serial NOR Flash Datasheet

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3.3V Multi I/O with 4KB, 32KB & 64KB Sector/Block Erase

- 32M -bit Serial Flash
 - 4096K-byte
 - 256 bytes per programmable page
- Support SFDP & Unique ID
- Standard, Dual, Quad SPI
 - Standard SPI: SCLK, CS#, SI, SO, WP#, HOLD#
 - Dual SPI: SCLK, CS#, IO0, IO1, WP#, HOLD#
 - Quad SPI: SCLK, CS#, IO0, IO1, IO2, IO3
 - QPI: SCLK, CS#, IO0, IO1, IO2, IO3
- Flexible Architecture
 - Sector of 4K-byte
 - Block of 32/64k-byte
- Advanced security Features
 - 4*256-Byte Security Registers With OTP Lock
- Software/Hardware Write Protection
 - Write protect all/portion of memory via software
 - Enable/Disable protection with WP# Pin
 - Top or Bottom, Sector or Block selection
- Package Options
 - See 1.1 Available Ordering OPN
 - All Pb-free packages are compliant RoHS, Halogen-Free and REACH.

- Temperature Range & Moisture Sensitivity Level
 - Industrial Level Temperature. (-40 $^\circ C$ to +85 $^\circ C$), MSL3
- Low Power Consumption
 - 12uA typical standby current
 - 0.1uA typical power down current
- Single Power Supply Voltage:
 - 2.7~3.6V
- Minimum 100,000 Program/Erase Cycle
- High Speed Clock Frequency
 - 108MHz for fast read with 30PF load
 - Dual I/O Data transfer up to 216Mbits/s
 - Quad I/O Data transfer up to 344Mbits/s
 - QPI Mode Data transfer up to 288Mbits/s
 - Continuous Read With 8/16/32/64-byte Wrap

Program/Erase Speed

- Page Program time: 350us typical
- Sector Erase time: 70ms typical
- Block Erase time: 0.15/0.25s typical
- Chip Erase time: 10s typical



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1. GENERAL DESCRIPTION

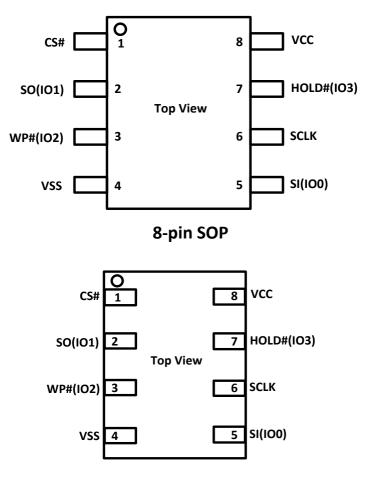
The XT25F32B-S (32M-bit) Serial flash supports the standard Serial Peripheral Interface (SPI), and supports the Dual/Quad SPI: Serial Clock, Chip Select, Serial Data I/O0 (SI), I/O1 (SO), I/O2 (WP#), and I/O3 (HOLD#). The Dual I/O data is transferred with speed of 216Mbits/s and the Quad I/O & Quad output data is transferred with speed of 344 Mbits/s.

1.1. Available Ordering OPN

OPN	Package Type	Package Carrier
XT25F32BSOIGU-S	SO8 150mil	Tube
XT25F32BSOIGT-S	SO8 150mil	Tape & Reel
XT25F32BSSIGU-S	SO8 208mil	Tube
XT25F32BSSIGT-S	SO8 208mil	Tape & Reel
XT25F32BWOIGT-S	WSON8 6x5mm	Tape & Reel
XT25F32BDFIGT-S	DFN8 2x3x0.55 mm	Tape & Reel
XT25F32BDXIGT-S	DFN8 4x3x0.55 mm	Tape & Reel



1.2. Connection Diagram



8-pin DFN



1.3. Pin Description

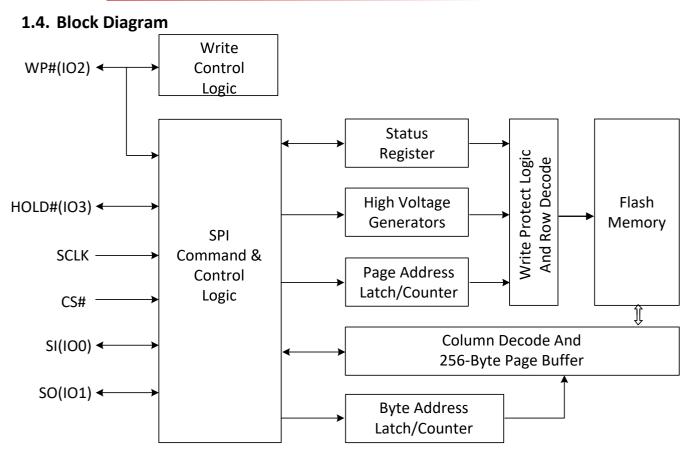
Pin Name I/O [Description
CS#	I	Chip Select Input
SO (IO1)	I/O	Data Output (Data Input Output 1)
WP# (IO2)	I/O	Write Protect Input (Data Input Output 2)
VSS		Ground
SI (100)	I/O	Data Input (Data Input Output 0)
SCLK	Ι	Serial Clock Input
HOLD# (IO3)	I/O	Hold Input (Data Input Output 3)
VCC		Power Supply

Notes:

1. IO0 and IO1 are used for Standard and Dual SPI instructions

2. IO0 – IO3 are used for Quad SPI instructions, WP# & HOLD# functions are only available for Standard/Dual SPI.







2. MEMORY ORGANIZATION

XT25F32B-S

Each Device has	Each block has	Each sector has	Each page has	Remark
4M	64K/32K	4К	256	bytes
16K	256/128	16	-	pages
1K	16/8	-	-	sectors
64/128	-	-	-	blocks

UNIFORM BLOCK/SECTOR ARCHITECTURE

XT25F32B-S 64K Bytes Block/Sector Architecture

Block	Sector	Address	range
	1023	3FF000H	3FFFFH
63			
	1008	3F0000H	3F0FFFH
	1007	3EF000H	3EFFFFH
62			
	992	3E0000H	3E0FFFH
	47	02F000H	02FFFFH
2			
	32	020000H	020FFFH
	31	01F000H	01FFFFH
1			
	16	010000H	010FFFH
	15	00F000H	00FFFFH
0			
	0	000000H	000FFFH



3. DEVICE OPERATION

SPI Mode

Standard SPI

The XT25F32B-S features a serial peripheral interface on 4 signals bus: Serial Clock (SCLK), Chip Select (CS#), Serial Data Input (SI) and Serial Data Output (SO). Both SPI bus mode 0 and 3 are supported. Input data is latched on the rising edge of SCLK and data shifts out on the falling edge of SCLK. Note: "WP#" & "HOLD#" pin require external pull-up.

Dual SPI

The XT25F32B-S supports Dual SPI operation when using the "Dual Output Fast Read" and "Dual I/O Fast Read" (3BH and BBH) commands. These commands allow data to be transferred to or from the device at two times the rate of the standard SPI. When using the Dual SPI command the SI and SO pins become bidirectional I/O pins: IO0 and IO1. Note: "WP#" & "HOLD#" pin require external pull-up.

Quad SPI

The XT25F32B-S supports Quad SPI operation when using the "Quad Output Fast Read", "Quad I/O Fast Read", "Quad I/O Word Fast Read" (6BH, EBH, E7H) commands. These commands allow data to be transferred to or from the device at four times the rate of the standard SPI. When using the Quad SPI command the SI and SO pins become bidirectional I/O pins: IOO and IO1, and WP# and HOLD# pins become IO2 and IO3. Quad SPI commands require the non-volatile Quad Enable bit (QE) in Status Register to be set.

QPI

The XT25F32B-S supports Quad Peripheral Interface (QPI) operations only when the device is switched from Standard/Dual/Quad SPI mode to QPI mode using the "Enable the QPI (38H)" command. The QPI mode utilizes all four IO pins to input the command code. Standard/Dual/Quad SPI mode and QPI mode are exclusive. Only one mode can be active at any given times. "Enable the QPI (38H)" and "Disable the QPI (FFH)" commands are used to switch between these two modes. Upon power-up and after software reset using "Reset (99H)" command, the default state of the device is Standard/Dual/Quad SPI mode. The QPI mode requires the non-volatile Quad Enable bit (QE) in Status Register to be set.

Hold

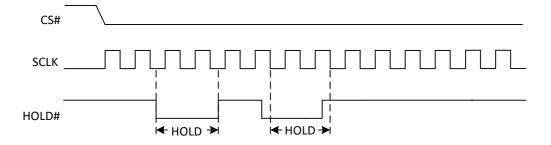
The HOLD# signal goes low to stop any serial communications with the device, but doesn't stop the operation of write status register, programming, or erasing in progress.

The operation of HOLD, need CS# keep low, and starts on falling edge of the HOLD# signal, with SCLK signal being low (if SCLK is not being low, HOLD operation will not start until SCLK being low). The HOLD condition ends on rising edge of HOLD# signal with SCLK being low (If SCLK is not being low, HOLD operation will not end until SCLK being low).

Both SI and SCLK don't care during the HOLD operation, if CS# drives high during HOLD operation, it will reset the internal logic of the device. To re-start communication with chip, the HOLD# must be at high and then CS# must be at low.



Figure1. Hold Condition



4. DATA PROTECTION

The XT25F32B-S provides the following data protection methods:

■ Write Enable (WREN) command: The WREN command is set the Write Enable Latch bit (WEL). The WEL

bit will return to reset by the following situation:

- Power-Up
- Write Disable (WRDI)
- Write Status Register (WRSR)
- Page Program (PP)
- Sector Erase (SE) / Block Erase (BE) / Chip Erase (CE)
- Erase Security Register / Program Security Register
- Software Protection Mode: The Block Protect (BP4, BP3, BP2, BP1, BP0) bits and CMP bit define the section of the memory array that can be read but not change.
- Hardware Protection Mode: WP# goes low to prevent writing status register.
- Deep Power-Down Mode: In Deep Power-Down Mode, all commands are ignored except the Release from Deep Power-Down Mode command (ABH) and software reset (66H+99H).



Table1.0 XT25F32B-S Protected area size (CMP=0)

	Status R	egister	Content			Memory Content					
BP4	BP3	BP2	BP1	BP0	Blocks	Addresses	Density	Portion			
Х	Х	0	0	0	NONE	NONE	NONE	NONE			
0	0	0	0	1	63	3F0000H-3FFFFFH	64KB	Upper 1/64			
0	0	0	1	0	62 to 63	3E0000H-3FFFFFH	128KB	Upper 1/32			
0	0	0	1	1	60 to 63	3C0000H-3FFFFFH	256KB	Upper 1/16			
0	0	1	0	0	56 to 63	380000H-3FFFFFH	512KB	Upper 1/8			
0	0	1	0	1	48 to 63	300000H-3FFFFFH	1MB	Upper 1/4			
0	0	1	1	0	32 to 63	200000H-3FFFFFH	2MB	Upper 1/2			
0	1	0	0	1	0	000000H-00FFFFH	64KB	Lower 1/64			
0	1	0	1	0	0 to 1	000000H-01FFFFH	128KB	Lower 1/32			
0	1	0	1	1	0 to 3	000000H-03FFFFH	256KB	Lower 1/16			
0	1	1	0	0	0 to 7	000000H-07FFFH	512KB	Lower 1/8			
0	1	1	0	1	0 to 15	000000H-0FFFFH	1MB	Lower 1/4			
0	1	1	1	0	0 to 31	000000H-1FFFFFH	2MB	Lower 1/2			
Х	Х	1	1	1	0 to 63	000000H-3FFFFFH	4MB	ALL			
1	0	0	0	1	63	3FF000H-3FFFFFH	4KB	Top Block			
1	0	0	1	0	63	3FE000H-3FFFFFH	8KB	Top Block			
1	0	0	1	1	63	3FC000H-3FFFFFH	16KB	Top Block			
1	0	1	0	Х	63	3F8000H-3FFFFFH	32KB	Top Block			
1	0	1	1	0	63	3F8000H-3FFFFFH	32KB	Top Block			
1	1	0	0	1	0	000000H-000FFFH	4KB	Bottom Block			
1	1	0	1	0	0	000000H-001FFFH	8KB	Bottom Block			
1	1	0	1	1	0	000000H-003FFFH	16KB	Bottom Block			
1	1	1	0	Х	0	000000H-007FFFH	32KB	Bottom Block			
1	1	1	1	0	0	000000H-007FFFH	32KB	Bottom Block			



Table1.1 XT25F32B-S Protected area size (CMP=1)

	Status R	egister	Content			Memory Content				
BP4	BP3	BP2	BP1	BP0	Blocks	Addresses	Density	Portion		
Х	Х	0	0	0	ALL	000000H-3FFFFFH	4MB	ALL		
0	0	0	0	1	0 to 62	000000H-3EFFFFH	4032KB	Lower 63/64		
0	0	0	1	0	0 to 61	000000H-3DFFFFH	3968KB	Lower 31/32		
0	0	0	1	1	0 to 59	000000H-3BFFFFH	3840KB	Lower 15/16		
0	0	1	0	0	0 to 55	000000H-37FFFFH	3584KB	Lower 7/8		
0	0	1	0	1	0 to 47	000000H-2FFFFFH	3MB	Lower 3/4		
0	0	1	1	0	0 to 31	000000H-1FFFFFH	2MB	Lower 1/2		
0	1	0	0	1	1 to 63	000000H-00FFFFH	4032KB	Upper 63/64		
0	1	0	1	0	2 to 63	000000H-01FFFFH	3968KB	Upper 31/32		
0	1	0	1	1	4 to 63	000000H-03FFFFH	3840KB	Upper 15/16		
0	1	1	0	0	8 to 63	000000H-07FFFFH	3584KB	Upper 7/8		
0	1	1	0	1	16 to 63	000000H-0FFFFH	3MB	Upper 3/4		
0	1	1	1	0	32 to 63	000000H-1FFFFFH	2MB	Upper 1/2		
Х	Х	1	1	1	NONE	NONE	NONE	NONE		
1	0	0	0	1	0 to 63	000000H-3FEFFFH	4092KB	L-1023/1024		
1	0	0	1	0	0 to 63	000000H-3FDFFFH	4088KB	L-511/512		
1	0	0	1	1	0 to 63	000000H-3FBFFFH	4080KB	L-255/256		
1	0	1	0	Х	0 to 63	000000H-3F7FFFH	4064KB	L-127/128		
1	0	1	1	0	0 to 63	000000H-3F7FFFH	4064KB	L-127/128		
1	1	0	0	1	0 to 63	001000H-3FFFFFH	4092KB	U-1023/1024		
1	1	0	1	0	0 to 63	002000H-3FFFFFH	4088KB	U-511/512		
1	1	0	1	1	0 to 63	004000H-3FFFFFH	4080KB	U-255/256		
1	1	1	0	Х	0 to 63	008000H-3FFFFFH	4064KB	U-127/128		
1	1	1	1	0	0 to 63	008000H-3FFFFFH	4064KB	U-127/128		



5. STATUS REGISTER

S15	S14	S13	S12	S11	S10	S 9	S 8
Reserved	СМР	Reserved	Reserved	Reserved	LB	QE	SRP1

S7	S6	S5	S 4	S3	S2	S1	SO
SRPO	BP4	BP3	BP2	BP1	BPO	WEL	WIP

The status and control bits of the Status Register are as follows:

WIP bit.

The Write In Progress (WIP) bit indicates whether the memory is busy in program/erase/write status register progress. When WIP bit sets to 1, means the device is busy in program/erase/write status register progress, when WIP bit sets 0, means the device is not in program/erase/write status register progress.

WEL bit.

The Write Enable Latch (WEL) bit indicates the status of the internal Write Enable Latch. When set to 1 the internal Write Enable Latch is set, when set to 0 the internal Write Enable Latch is reset and no Write Status Register, Program or Erase command is accepted.

BP4, BP3, BP2, BP1, BP0 bits.

The Block Protect (BP4, BP3, BP2, BP1, BP0) bits are non-volatile. They define the size of the area to be software protected against Program and Erase commands. These bits are written with the Write Status Register (WRSR) command. When the Block Protect (BP4, BP3, BP2, BP1, BP0) bits are set to 1, the relevant memory area (as defined in Table1) becomes protected against Page Program (PP), Sector Erase (SE) and Block Erase (BE) commands. The Block Protect (BP4, BP3, BP2, BP1, BP0) bits can be written provided that the Hardware Protected mode has not been set. The Chip Erase (CE) command is executed if the Block Protect (BP2, BP1, BP0) bits are 0 and CMP=0 or the Block Protect (BP2, BP1, BP0) bits are 1 and CMP=1.

SRP1, SRP0 bits.

The Status Register Protect (SRP1 and SRP0) bits are non-volatile Read/Write bits in the status register. The SRP bits control the method of write protection: software protection, hardware protection, power supply lock-down or one-time programmable protection.

SRP1	SRPO	WP#	Status Register	Description				
0	0	X Software Protected		The Status Register can be written to after a Write Enable command, WEL=1. (Default)				
0	1	0	Hardware Protected WP#=0, the Status Register locked and cannot be written until the next power-up.					
0	1	1	Hardware Unprotected	WP#=1, the Status Register is unlocked and can be written to after a Write Enable command, WEL=1.				
1	0	х	Power Supply Lock- Down(1)(2)	Status Register is protected and cannot be written to again until the next Power-Down, Power-Up cycle.				
1	1 X One-Time Program(2)		One-Time Program(2)	Status Register is permanently protected and cannot be writ- ten to.				



NOTE:

- 1. When SRP1, SRP0= (1, 0), a Power-Down, Power-Up cycle will change SRP1, SRP0 to (0, 0) state.
- 2. This feature is available on special order(XT25F32BxxSx-S). Please contact XTX for details.

QE bit.

The Quad Enable (QE) bit is a non-volatile Read/Write bit in the Status Register that allows Quad operation. When the QE bit is set to 0 (Default) the WP# pin and HOLD# pin are enable. When the QE pin is set to 1, the Quad IO2 and IO3 pins are enabled. (The QE bit should never be set to 1 during standard SPI or Dual SPI operation if the WP# or HOLD# pins are tied directly to the power supply or ground).

LB bit.

The LB bit is a non-volatile One Time Program (OTP) bit in Status Register (S10) that provide the write protect control and status to the Security Registers. The default state of LB is 0, the security registers are unlocked. LB can be set to 1 using the Write Register instruction. LB is One Time Programmable, once it's set to 1, the Security Registers will become read-only permanently.

CMP bit.

The CMP bit is a non-volatile Read/Write bit in the Status Register (S14). It is used in conjunction with the BP4-BP0 bits to provide more flexibility for the array protection. Please see the Status registers Memory Protection table for details. The default setting is CMP=0.



6. COMMANDS DESCRIPTION

All commands, addresses and data are shifted in and out of the device, beginning with the most significant bit on the first rising edge of SCLK after CS# is driven low. Then, the one-byte command code must be shifted in to the device, most significant bit first on SI, each bit being latched on the rising edges of SCLK.

See Table2, every command sequence starts with a one-byte command code. Depending on the command, this might be followed by address bytes, or by data bytes, or by both or none. CS# must be driven high after the last bit of the command sequence has been shifted in. For the command of Read, Fast Read, Read Status Register or Release from Deep Power-Down, and Read Device ID, the shifted-in command sequence is followed by a data-out sequence. CS# can be driven high after any bit of the data-out sequence is being shifted out.

For the command of Page Program, Sector Erase, Block Erase, Chip Erase, Write Status Register, Write Enable, Write Disable or Deep Power-Down command, CS# must be driven high exactly at a byte boundary, otherwise the command is rejected, and is not executed. That is CS# must be driven high when the number of clock pulses after CS# being driven low is an exact multiple of eight. For Page Program, if at any time the input byte is not a full byte, nothing will happen and WEL will not be reset.

Command Name	Byte1	Byte2	Byte3	Byte4	Byte5	Byte6	n-Bytes
Write Enable	06H						
Write Enable for Volatile Status Register	50H						
Write Disable	04H						
Read Status Register	05H	(S7-S0)					(continuous)
Read Status Register-1	35H	(S15-S8)					(continuous)
Write Status Register	01H	(S7-S0)	(S15-S8)				(continuous)
Read Data	03H	A23-A16	A15-A8	A7-A0	(D7-D0)	(Next byte)	(continuous)
Fast Read	OBH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)	(continuous)
Dual Output Fast Read	3BH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)(1)	(continuous)
Dual I/O Fast Read			A7-A0				
Dual I/O Fast Reau	BBH	A23-A8(2)	M7-M0(2)	(D7-D0)(1)			(continuous)
Quad Output Fast Read	6BH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)(3)	(continuous)
Quad I/O Fast Read	EBH	A23-A0 M7-M0(4)	Dummy(5)	(D7-D0)(3)			(continuous)
Quad I/O Word Fast		A23-A0					
Read	E7H	M7-M0(4)	Dummy(6)	(D7-D0)(3)			(continuous)
Continuous Read Reset	FFH						
Page Program	02H	A23-A16	A15-A8	A7-A0	(D7-D0)	(Next byte)	
Quad Page Program	32H	A23-A16	A15-A8	A7-A0	(D7-D0)(3)		
Sector Erase	20H	A23-A16	A15-A8	A7-A0			
Block Erase(32KB)	52H	A23-A16	A15-A8	A7-A0			
Block Erase(64KB)	D8H	A23-A16	A15-A8	A7-A0			
Chip Erase	C7/60H						
Enable QPI	38H						
Set Burst with Wrap	77H	dummy	dummy	dummy	W6-W4		

Table 2. Commands



Deep Power-Down	B9H						
Release From Deep Power-Down, And Read Device ID	ABH	dummy	dummy	dummy	(DID7-DID0)		
Release From Deep Power-Down	ABH						(continuous)
Manufacturer/Device ID	90H	dummy	dummy	00Н	(MID7- MID0)	(DID7-DID0)	
Manufacturer/Device ID by Dual I/O	92H	A23-A8	A7-A0, M[7:0]	(M7-M0) (ID7-ID0)			(continuous)
Manufacturer/Device ID by Quad I/O	94H	A23-A0, M[7:0]	dummy	(M7-M0) (ID7-ID0)			(continuous)
Read Serial Flash Discoverable Parameters	5AH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)	(continuous)
Read Unique ID	5AH	00H	01H	94H	dummy	(D7-D0)	(continuous)
Read Identification	9FH	(MID7- MID0)	(JDID15-J DID8)	(DO)			(continuous)
Erase Security Register(8)	44H	A23-A16	A15-A8	A7-A0			(continuous)
Program Security							
Register(8)	42H	A23-A16	A15-A8	A7-A0	(D7-D0)	(Next byte)	
Read Security Register(8)							
	48H	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)	
Enable Reset	66H						
Reset	99H						



Table2a. Commands (QPI)

Command Name	Byte1	Byte2	Byte3	Byte4	Byte5	Byte6
Clock Number	(0,1)	(2,3)	(4,5)	(6,7)	(8,9)	(10,11)
Write Enable	06H					
Write Enable for Volatile Status Register	50H					
Write Disable	04H					
Read Status Register	05H	(S7-S0)				
Read Status Register-1	35H	(S15-S8)				
Write Status Register	01H	(S7-S0)	(S15-S8)			
Page Program	02H	A23-A16	A15-A8	A7-A0	(D7-D0)	(Next byte)
Sector Erase	20H	A23-A16	A15-A8	A7-A0		
Block Erase(32KB)	52H	A23-A16	A15-A8	A7-A0		
Block Erase(64KB)	D8H	A23-A16	A15-A8	A7-A0		
Chip Erase	C7/60H					
Deep Power-Down	B9H					
Set Read Parameters	СОН	P7-P0				
Fast Read	OBH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)
Burst Read with Wrap	0CH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)
Quad I/O Fast Read	EBH	A23-A0	dummy(5)	(D7-D0)(3)		
Release from Deep Power- Down, And Read Device ID(10)	ABH	dummy	dummy	dummy * N	(ID7-ID0)	
Manufacturer/Device ID(11)	90H	dummyx2	00H	dummy * N	MID7~MID0	(ID7-ID0)
Disable QPI	FFH					
Enable Reset	66H					
Reset	99H					

NOTE:

1. Dual Output data

IO0 = (D6, D4, D2, D0)

IO1 = (D7, D5, D3, D1)

2. Dual Input Address

IO0 = A22, A20, A18, A16, A14, A12, A10, A8, A6, A4, A2, A0, M6, M4, M2, M0

IO1 = A23, A21, A19, A17, A15, A13, A11, A9, A7, A5, A3, A1, M7, M5, M3, M1

3. Quad Output Data

IO0 = (D4, D0,) IO1 = (D5, D1,) IO2 = (D6, D2,) IO3 = (D7, D3,)



4. Quad Input Address

IO0 = A20, A16, A12, A8, A4, A0, M4, M0 IO1 = A21, A17, A13, A9, A5, A1, M5, M1 IO2 = A22, A18, A14, A10, A6, A2, M6, M2 IO3 = A23, A19, A15, A11, A7, A3, M7, M3

5. Quad I/O Fast Read Data

IO0 = (x, x, x, x, D4, D0,...) IO1 = (x, x, x, x, D5, D1,...) IO2 = (x, x, x, x, D6, D2,...) IO3 = (x, x, x, x, D7, D3,...)

6. Quad I/O Word Fast Read Data

IO0 = (x, x, D4, D0,...)

```
IO1 = (x, x, D5, D1,...)
```

```
IO2 = (x, x, D6, D2,...)
```

```
IO3 = (x, x, D7, D3,...)
```

7. Quad I/O Word Fast Read Data: the lowest address bit must be 0.

8. Security Registers Address:

Security Register1: A23-A16=00H, A15-A8=01H, A7-A0= Byte Address; Security Register2: A23-A16=00H, A15-A8=02H, A7-A0= Byte Address; Security Register3: A23-A16=00H, A15-A8=03H, A7-A0= Byte Address. Security Register4: A23-A16=00H, A15-A8=04H, A7-A0= Byte Address.

9. QPI Command, Address, Data input/output format:

 CLK#
 0
 1
 2
 3
 4
 5
 6
 7
 8
 9
 10
 11

 IO0 = C4, C0, A20, A16, A12, A8, A4, A0, D4, D0, D4, D0
 IO4, D0, D4, D0
 IO4, D0
 IO4, D0

 IO1 = C5, C1, A21, A17, A13, A9, A5, A1, D5, D1, I05, D1
 IO5, D1
 IO5, D1
 IO5, D1

 IO2 = C6, C2, A22, A18, A14, A10, A6, A2, D6, D2, I06, D2
 IO6, D2
 IO6, D2
 IO6, D2

 IO3 = C7, C3, A23, A19, A15, A11, A7, A3, D7, D3, D7, D3
 IO7, D3
 IO7, D3
 IO7, D3

10. QPI mode: Release from Deep Power-Down, And Read Device ID (ABH)

N dummy cycles should be inserted before ID read cycle, refer to COH command

11. QPI mode: Manufacturer/Device ID (90H)

N dummy cycles should be inserted before ID read cycle, refer to COH command

Table of ID Definitions:

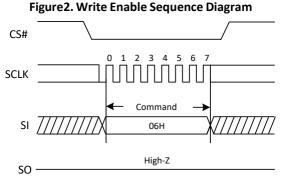
XT25F32B-S

Operation Code	MID7-MID0	ID15-ID8	ID7-ID0
9FH	ОВ	40	16
90H	ОВ		15
АВН			15

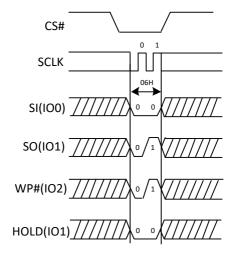


6.1. Write Enable (WREN) (06H)

The Write Enable (WREN) command is for setting the Write Enable Latch (WEL) bit. The Write Enable Latch (WEL) bit must be set prior to every Page Program (PP), Sector Erase (SE), Block Erase (BE), Chip Erase (CE), Erase Security Register, Program Security Register and Write Status Register (WRSR) command. The Write Enable (WREN) command sequence: CS# goes low -> Sending the Write Enable command -> CS# goes high.







6.2. Write Enable for Volatile Status Register (50H)

The non-volatile Status Register bits can also be written to as volatile bits. This gives more flexibility to change the system configuration and memory protection schemes quickly without waiting for the typical non-volatile bit write cycles or affecting the endurance of the Status Register non-volatile bits. The Write Enable for Volatile Status Register command must be issued prior to a Write Status Register command and any other commands can't be inserted between them. Otherwise, Write Enable for Volatile Status Register will be cleared. The Write Enable for Volatile Status Register command will not set the Write Enable Latch bit, it is only valid for the Write Status Register command to change the volatile Status Register bit values.

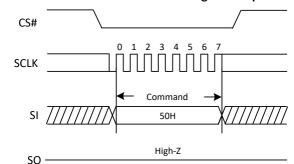
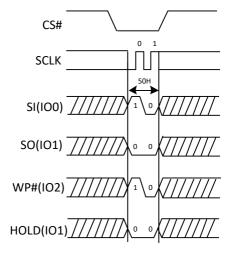


Figure3. Write Enable for Volatile Status Register Sequence Diagram

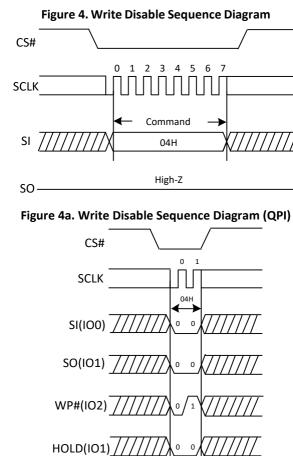


Figure 3a. Write Enable for Volatile Status Register Sequence Diagram (QPI)



6.3. Write Disable (WRDI) (04H)

The Write Disable command is for resetting the Write Enable Latch (WEL) bit. The Write Disable command sequence: CS# goes low \rightarrow sending the Write Disable command \rightarrow CS# goes high. The WEL bit is reset by following condition: Power-up and upon completion of the Write Status Register, Page Program, Sector Erase, Block Erase and Chip Erase commands.

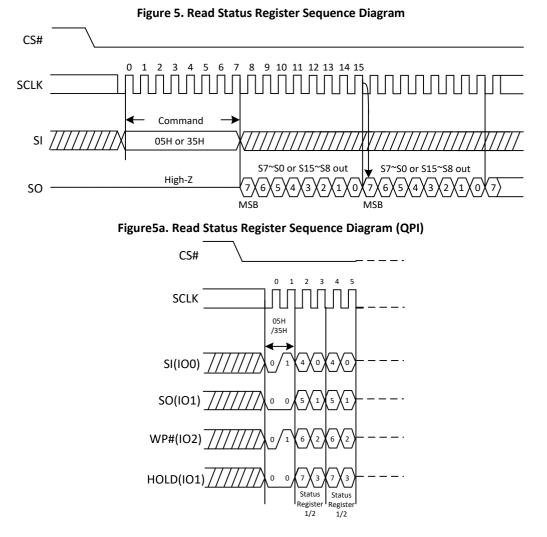


0 0



6.4. Read Status Register (RDSR) (05H or 35H)

The Read Status Register (RDSR) command is for reading the Status Register. The Status Register can be read at any time, even while a Program, Erase or Write Status Register cycle is in progress. When one of these cycles is in progress, it is recommended to check the Write In Progress (WIP) bit before sending a new command to the device. It is also possible to read the Status Register continuously. For command code "05H", the SO will output Status Register bits S7~S0. The command code "35H", the SO will output Status Register bits S15~S8.



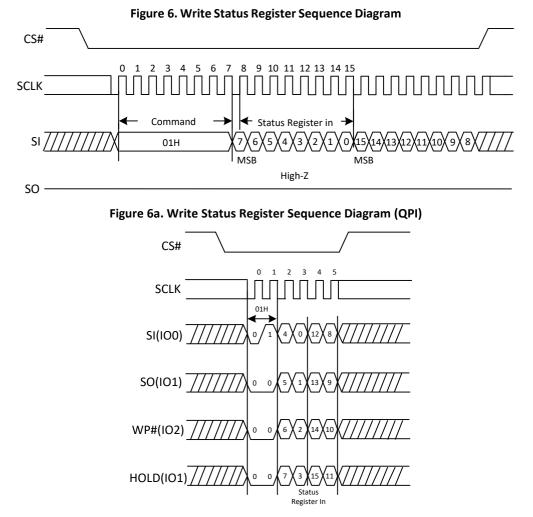


6.5. Write Status Register (WRSR) (01H)

The Write Status Register (WRSR) command allows new values to be written to the Status Register. Before it can be accepted, a Write Enable (WREN) command must previously have been executed. After the Write Enable (WREN) command has been decoded and executed, the device sets the Write Enable Latch (WEL).

The Write Status Register (WRSR) command has no effect on S15, S13, S12, S11, S1 and S0 of the Status Register. CS# must be driven high after the eighth or sixteen bit of the data byte has been latched in. If not, the Write Status Register (WRSR) command is not executed. If CS# is driven high after eighth bit of the data byte, the CMP and QE bit will be cleared to 0. As soon as CS# is driven high, the self-timed Write Status Register cycle (whose duration is tW) is initiated. While the Write Status Register cycle is in progress, the Status Register may still be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Write Status Register cycle, and is 0 when it is completed. When the cycle is completed, the Write Enable Latch (WEL) is reset.

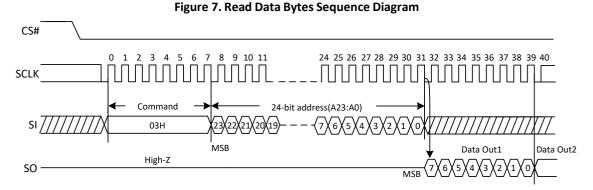
The Write Status Register (WRSR) command allows the user to change the values of the Block Protect (BP4, BP3, BP2, BP1, BP0) bits, to define the size of the area that is to be treated as read-only, as defined in Table1. The Write Status Register (WRSR) command also allows the user to set or reset the Status Register Protect (SRP) bit in accordance with the Write Protect (WP#) signal. The Status Register Protect (SRP) bit and Write Protect (WP#) signal allow the device to be put in the Hardware Protected Mode. The Write Status Register (WRSR) command is not executed once the Hardware Protected Mode is entered.





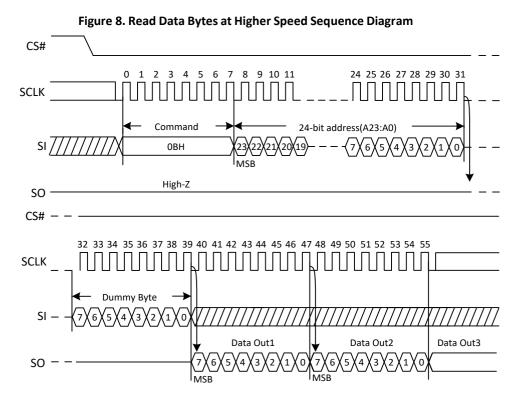
6.6. Read Data Bytes (READ) (03H)

The Read Data Bytes (READ) command is followed by a 3-byte address (A23-A0), each bit being latched-in during the rising edge of SCLK. Then the memory content, at that address, is shifted out on SO, each bit being shifted out, at a Max frequency fR, during the falling edge of SCLK. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out. The whole memory can, therefore, be read with a single Read Data Bytes (READ) command. Any Read Data Bytes (READ) command, while an Erase, Program or Write cycle is in progress, is rejected without having any effects on the cycle that is in progress.



6.7. Read Data Bytes At Higher Speed (Fast Read) (0BH)

The Read Data Bytes at Higher Speed (Fast Read) command is for fast reading data out. It is followed by a 3byte address (A23-A0) and a dummy byte, each bit being latched-in during the rising edge of SCLK. Then the memory content, at that address, is shifted out on SO, each bit being shifted out, at a Max frequency fC, during the falling edge of SCLK. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out.





Fast Read (OBH) in QPI mode

The Fast Read command is also supported in QPI mode. In QPI mode, the number of dummy clocks is configured by the "Set Read Parameters (COH)" command to accommodate a wide range application with different needs for either maximum Fast Read frequency or minimum data access latency. Depending on the Read Parameter Bits P[5:4] setting, the number of dummy clocks can be configured as either 4/6/8. When the dummy cycle is configured to 4, addr [0] input must be 0.

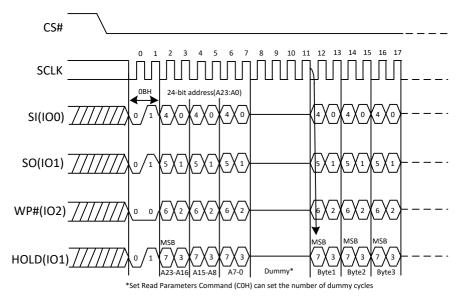
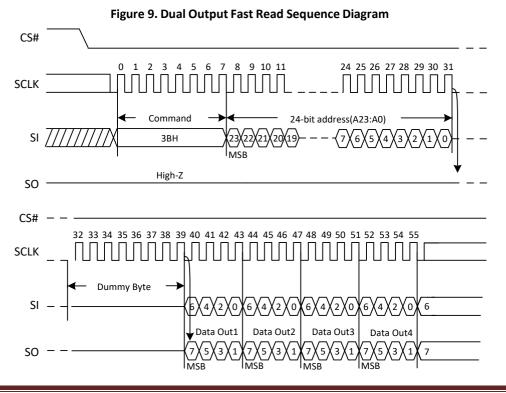


Figure 8a. Read Data Bytes at Higher Speed Sequence Diagram (QPI)

6.8. Dual Output Fast Read (3BH)

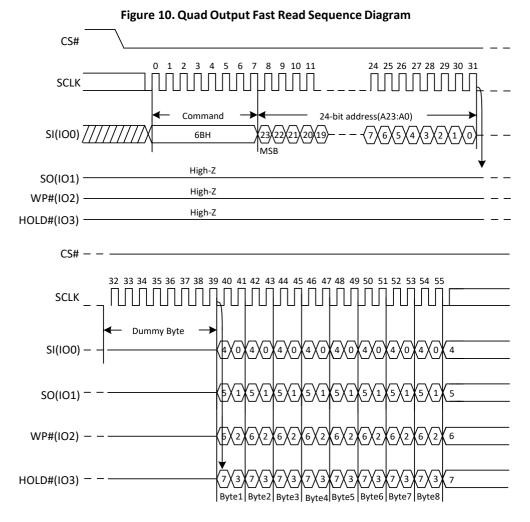
The Dual Output Fast Read command is followed by 3-byte address (A23-A0) and a dummy byte, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 2-bit per clock cycle from SI and SO. The command sequence is shown in Figure 9. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out.





6.9. Quad Output Fast Read (6BH)

The Quad Output Fast Read command is followed by 3-byte address (A23-A0) and a dummy byte, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 4-bit per clock cycle from IO3, IO2, IO1 and IO0. The command sequence is shown in Figure 10. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out.



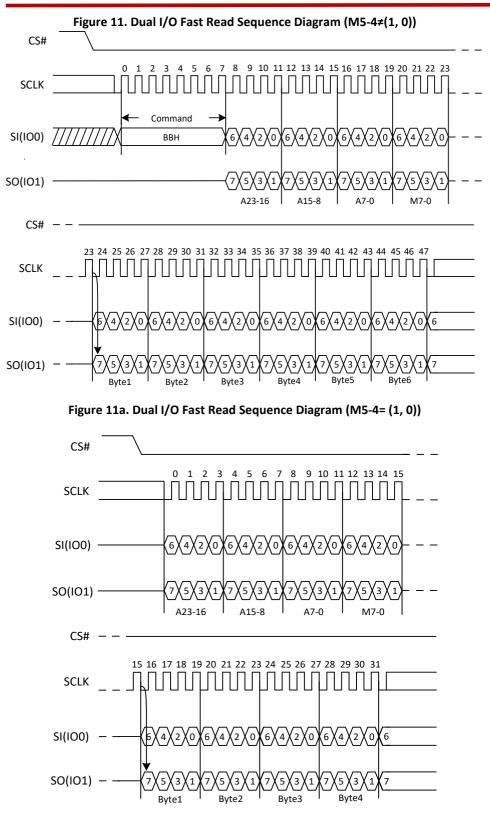
6.10. Dual I/O Fast Read (BBH)

The Dual I/O Fast Read command is similar to the Dual Output Fast Read command but with the capability to input the 3-byte address (A23-0) and a "Continuous Read Mode" byte 2-bit per clock by SI and SO, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 2-bit per clock cycle from SI and SO. The command sequence is shown in Figure 11. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out.

Dual I/O Fast Read with "Continuous Read Mode"

The Dual I/O Fast Read command can further reduce command overhead through setting the "Continuous Read Mode" bits (M7- 0) after the input 3-byte address (A23-A0). If the "Continuous Read Mode" bits (M5- 4) =(1, 0), then the next Dual I/O Fast Read command (after CS# is raised and then lowered) does not require the BBH command code. The command sequence is shown in figure 11a. If the "Continuous Read Mode" bits (M5- 4) do not equal (1, 0), the next command requires the first BBH command code, thus returning to normal operation. A "Continuous Read Mode" Reset command can be used to reset (M5- 4) before issuing normal command.





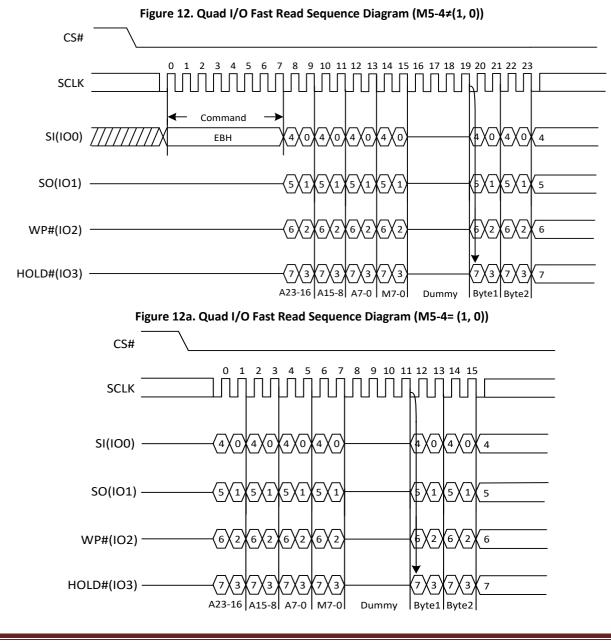


6.11. Quad I/O Fast Read (EBH)

The Quad I/O Fast Read command is similar to the Dual I/O Fast Read command but with the capability to input the 3-byte address (A23-0) and a "Continuous Read Mode" byte and 4-dummy clock 4-bit per clock by IOO, IO1, IO3, IO4, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 4-bit per clock cycle from IO0, IO1, IO2, IO3. The command sequence is shown in Figure 12. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out. The Quad Enable bit (QE) of Status Register (S9) must be set to enable for the Quad I/O Fast read command.

Quad I/O Fast Read with "Continuous Read Mode"

The Quad I/O Fast Read command can further reduce command overhead through setting the "Continuous Read Mode" bits (M7-0) after the input 3-byte address (A23-A0). If the "Continuous Read Mode" bits (M5- 4) =(1, 0), then the next Quad I/O Fast Read command (after CS# is raised and then lowered) does not require the EBH command code. The command sequence is shown in Figure 12a. If the "Continuous Read Mode" (M5- 4) do not equal (1, 0), the next command requires the first EBH command code, thus returning to normal operation. A "Continuous Read Mode" Reset command can be used to reset (M5- 4) before issuing normal command.





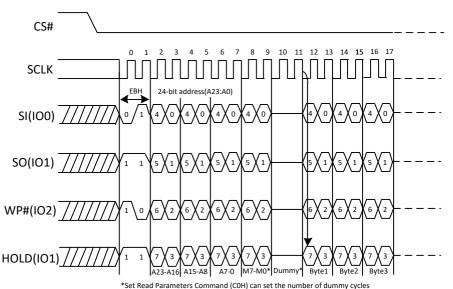
Quad I/O Fast Read with ""8/16/32/64-Byte Wrap Around" in Standard SPI mode

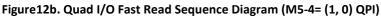
The Quad I/O Fast Read command can be used to access a specific portion within a page by issuing "Set Burst with Wrap" (77H) commands prior to EBH. The "Set Burst with Wrap" (77H) command can either enable or disable the "Wrap Around" feature for the following EBH commands. When "Wrap Around" is enabled, the data being accessed can be limited to either an 8/16/32/64-byte section of a 256-byte page. The output data starts at the initial address specified in the command, once it reaches the ending boundary of the 8/16/32/64-byte section, the output will wrap around the beginning boundary automatically until CS# is pulled high to terminate the command.

The Burst with Wrap feature allows applications that use cache to quickly fetch a critical address and then fill the cache afterwards within a fixed length (8/16/32/64-byte) of data without issuing multiple read commands. The "Set Burst with Wrap" command allows three "Wrap Bits" W6-W4 to be set. The W4 bit is used to enable or disable the "Wrap Around" operation while W6-W5 is used to specify the length of the wrap around section within a page.

Quad I/O Fast Read (EBH) in QPI mode

The Quad I/O Fast Read command is also supported in QPI mode. See Figure12b. In QPI mode, the number of dummy clocks is configured by the "Set Read Parameters (COH)" command to accommodate a wide range application with different needs for either maximum Fast Read frequency or minimum data access latency. Depending on the Read Parameter Bits P[5:4] setting, the number of dummy clocks can be configured as either 4/6/8. When the dummy cycle is configured to 4, addr[0] input must be 0. In QPI mode, the "Continuous Read Mode" bits M7-M0 are also considered as dummy clocks. "Continuous Read Mode" feature is also available in QPI mode for Quad I/O Fast Read command. "Wrap Around" feature is not available in QPI mode for Quad I/O Fast Read command. "Wrap Around" feature is not available in QPI mode, a dedicated "Burst Read with Wrap" (OCH) command must be used.







6.12. Quad I/O Word Fast Read (E7H)

The Quad I/O Word Fast Read command is similar to the Quad I/O Fast Read command except that the lowest address bit (A0) must equal 0 and only 2-dummy clock. The command sequence is shown in followed Figure 13. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out. The Quad Enable bit (QE) of Status Register (S9) must be set to enable for the Quad I/O Word Fast read command.

Quad I/O Word Fast Read with "Continuous Read Mode"

The Quad I/O Word Fast Read command can further reduce command overhead through setting the "Continuous Read Mode" bits (M7-0) after the input 3-byte address (A23-A0). If the "Continuous Read Mode" bits (M5- 4) =(1, 0), then the next Quad I/O Word Fast Read command (after CS# is raised and then lowered) does not require the E7H command code. The command sequence is shown in followed Figure 13a. If the "Continuous Read Mode" bits (M5- 4) do not equal (1, 0), the next command requires the first E7H command code, thus returning to normal operation. A "Continuous Read Mode" Reset command can be used to reset (M7-0) before issuing normal command.

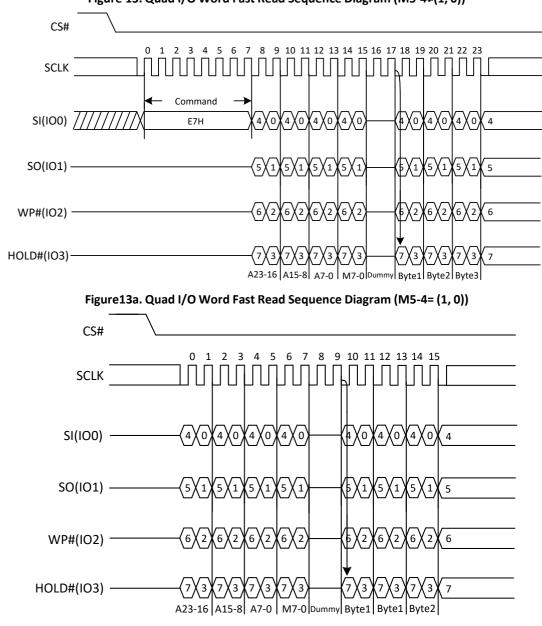


Figure 13. Quad I/O Word Fast Read Sequence Diagram (M5-4≠(1, 0))



Quad I/O Word Fast Read with "8/16/32/64-Byte Wrap Around" in Standard SPI mode

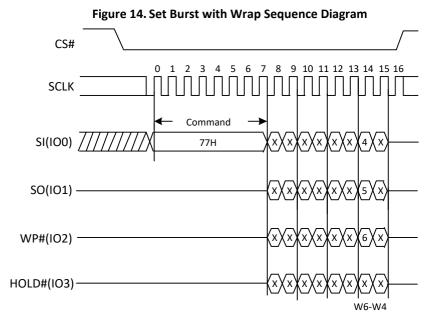
The Quad I/O Word Fast Read command can be used to access a specific portion within a page by issuing "Set Burst with Wrap" (77H) commands prior to E7H. The "Set Burst with Wrap" (77H) command can either enable or disable the "Wrap Around" feature for the following E7H commands. When "Wrap Around" is enabled, the data being accessed can be limited to either an 8/16/32/64-byte section of a 256-byte page. The output data starts at the initial address specified in the command, once it reaches the ending boundary of the 8/16/32/64-byte section, the output will wrap around the beginning boundary automatically until CS# is pulled high to terminate the command. The Burst with Wrap feature allows applications that use cache to quickly fetch a critical address and then fill the cache afterwards within a fixed length (8/16/32/64-byte) of data without issuing multiple read commands. The "Set Burst with Wrap" command allows three "Wrap Bits" W6-W4 to be set. The W4 bit is used to enable or disable the "Wrap Around" operation while W6-W5 is used to specify the length of the wrap around section within a page.

6.13. Set Burst with Wrap (77H)

The Set Burst with Wrap command is used in conjunction with "Quad I/O Fast Read" and "Quad I/O Word Fast Read" command to access a fixed length of 8/16/32/64-byte section within a 256-byte page, in standard SPI mode. The Set Burst with Wrap command sequence: CS# goes low \rightarrow Send Set Burst with Wrap command \rightarrow Send 24 dummy bits \rightarrow Send 8 bits "Wrap bits" \rightarrow CS# goes high

W6,W5	W	4=0	W4=1(default)		
	Wrap Around	Wrap Length	Wrap Around	Wrap Length	
0,0	Yes	8-byte	No	N/A	
0,1	Yes	16-byte	No	N/A	
1,0	Yes	32-byte	No	N/A	
1,1	Yes	64-byte	No	N/A	

If the W6-W4 bits are set by the Set Burst with Wrap command, all the following "Quad I/O Fast Read" and "Quad I/O Word Fast Read" command will use the W6-W4 setting to access the 8/16/32/64-byte section within any page. To exit the "Wrap Around" function and return to normal read operation, another Set Burst with Wrap command should be issued to set W4=1. In QPI mode, the "Burst Read with Wrap (0CH)" command should be used to perform the Read Operation with "Wrap Around" feature. The Wrap Length set by W5-W6 in Standard SPI mode is still valid in QPI mode and can also be re-configured by "Set Read Parameters (COH) command.





6.14. Page Program (PP) (02H)

The Page Program (PP) command is for programming the memory. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit before sending the Page Program command.

The Page Program (PP) command is entered by driving CS# Low, followed by the command code, three address bytes and at least one data byte on SI. If the 8 least significant address bits (A7-A0) are not all zero, all transmitted data that goes beyond the end of the current page are programmed from the start address of the same page (from the address whose 8 least significant bits (A7-A0) are all zero). CS# must be driven low for the entire duration of the sequence. The Page Program command sequence: CS# goes low \rightarrow sending Page Program command \rightarrow 3-byte address on SI \rightarrow at least 1 byte data on SI \rightarrow CS# goes high. The command sequence is shown in Figure15. If more than 256 bytes are sent to the device, previously latched data are discarded and the last 256 data bytes are guaranteed to be programmed correctly within the same page. If less than 256 data bytes are sent to device, they are correctly programmed at the requested addresses without having any effects on the other bytes of the same page. CS# must be driven high after the eighth bit of the last data byte has been latched in; otherwise the Page Program (PP) command is not executed.

As soon as CS# is driven high, the self-timed Page Program cycle (whose duration is tPP) is initiated. While the Page Program cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Page Program cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset.

A Page Program (PP) command applied to a page which is protected by the Block Protect (BP4, BP3, BP2, BP1, BP0) is not executed.

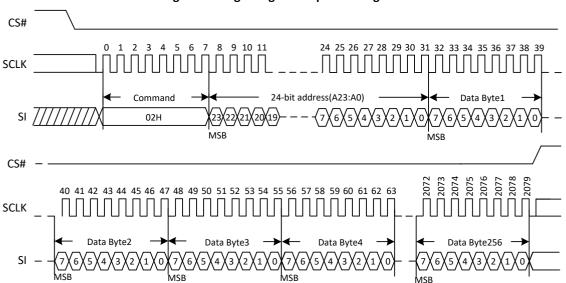
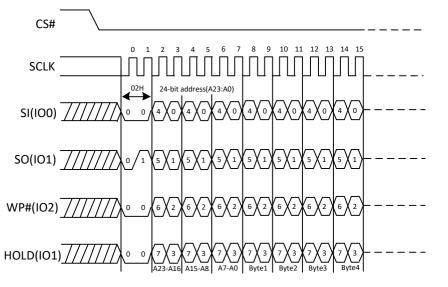


Figure 15. Page Program Sequence Diagram







6.15. Quad Page Program (QPP) (32H)

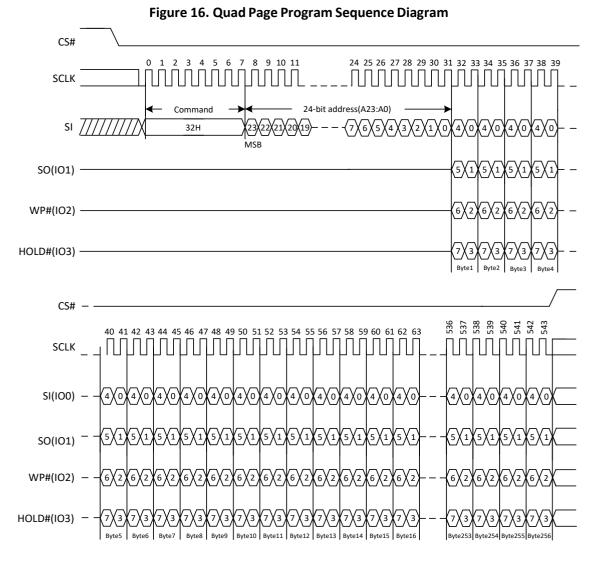
The Quad Page Program command is for programming the memory using four pins: IOO, IO1, IO2, and IO3. To use Quad Page Program the Quad enable in status register Bit9 must be set (QE=1). A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit before sending the Page Program command. The Quad Page Program command is entered by driving CS# Low, followed by the command code (32H), three address bytes and at least one data byte on IO pins.

The command sequence is shown in Figure 16. If more than 256 bytes are sent to the device, previously latched data are discarded and the last 256 data bytes are guaranteed to be programmed correctly within the same page. If less than 256 data bytes are sent to device, they are correctly programmed at the requested addresses without having any effects on the other bytes of the same page. CS# must be driven high after the eighth bit of the last data byte has been latched in; otherwise the Quad Page Program command is not executed.

As soon as CS# is driven high, the self-timed Quad Page Program cycle (whose duration is tPP) is initiated. While the Quad Page Program cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Quad Page Program cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset.

A Quad Page Program command applied to a page which is protected by the Block Protect (BP4, BP3, BP2, BP1, BP0) will not be executed.





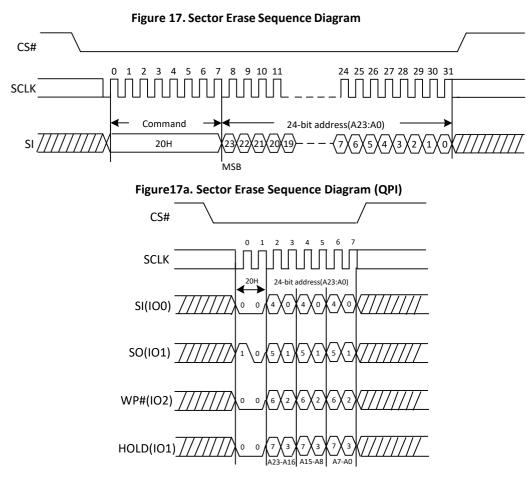
6.16. Sector Erase (SE) (20H)

The Sector Erase (SE) command is for erasing the all data of the chosen sector. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit. The Sector Erase (SE) command is entered by driving CS# low, followed by the command code, and 3-address byte on SI. Any address inside the sector is a valid address for the Sector Erase (SE) command. CS# must be driven low for the entire duration of the sequence.

The Sector Erase command sequence: CS# goes low \rightarrow sending Sector Erase command \rightarrow 3-byte address on SI \rightarrow CS# goes high. The command sequence is shown in Figure 17. CS# must be driven high after the eighth bit of the last address byte has been latched in; otherwise the Sector Erase (SE) command is not executed. As soon as CS# is driven high, the self-timed Sector Erase cycle (whose duration is tSE) is initiated. While the Sector Erase cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Sector Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. A Sector Erase (SE) com-mand applied to a sector which is protected by the Block Protect (BP4, BP3, BP2, BP1, BP0) bit (see Ta-ble1.0&1.1) will not be executed.

Note: Power disruption during erase operation will cause incomplete erase, thus recommend to perform a re-erase once power resume.





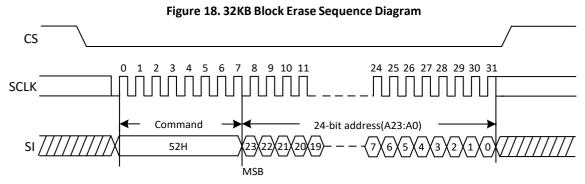
6.17. 32KB Block Erase (BE) (52H)

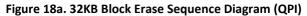
The 32KB Block Erase (BE) command is for erasing the all data of the chosen block. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit. The 32KB Block Erase (BE) command is entered by driving CS# low, followed by the command code, and three address bytes on SI. Any address inside the block is a valid address for the 32KB Block Erase (BE) command. CS# must be driven low for the entire duration of the sequence.

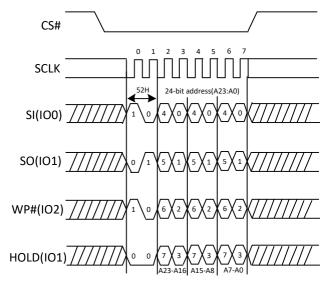
The 32KB Block Erase command sequence: CS# goes low \rightarrow sending 32KB Block Erase command \rightarrow 3-byte address on SI \rightarrow CS# goes high. The command sequence is shown in Figure 18. CS# must be driven high after the eighth bit of the last address byte has been latched in; otherwise the 32KB Block Erase (BE) command is not executed. As soon as CS# is driven high, the self-timed Block Erase cycle (whose duration is tBE) is initiated. While the Block Erase cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Block Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. A 32KB Block Erase (BE) command applied to a block which is protected by the Block Protect (BP4, BP3, BP2, BP1, BP0) bits (see Table1.0 & 1.1) will not be executed.

Note: Power disruption during erase operation will cause incomplete erase, thus recommend to perform a re-erase once power resume.









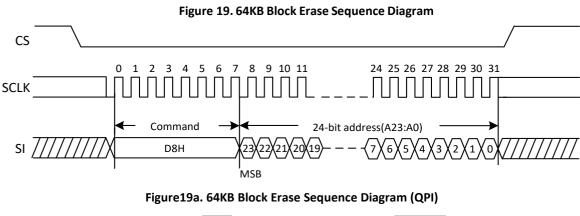
6.18. 64KB Block Erase (BE) (D8H)

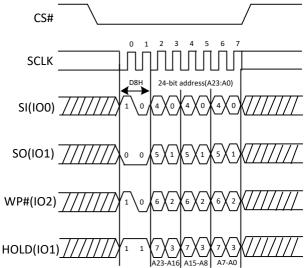
The 64KB Block Erase (BE) command is for erasing the all data of the chosen block. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit. The 64KB Block Erase (BE) command is entered by driving CS# low, followed by the command code, and three address bytes on SI. Any address inside the block is a valid address for the 64KB Block Erase (BE) command. CS# must be driven low for the entire duration of the sequence.

The 64KB Block Erase command sequence: CS# goes low \rightarrow sending 64KB Block Erase command \rightarrow 3-byte address on SI \rightarrow CS# goes high. The command sequence is shown in Figure 19. CS# must be driven high after the eighth bit of the last address byte has been latched in; otherwise the 64KB Block Erase (BE) command is not executed. As soon as CS# is driven high, the self-timed Block Erase cycle (whose duration is tBE) is initiated. While the Block Erase cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Block Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. A 64KB Block Erase (BE) command applied to a block which is protected by the Block Protect (BP4, BP3, BP2, BP1, BP0) bits (see Table1.0 & 1.1) will not be executed.

Note: Power disruption during erase operation will cause incomplete erase, thus recommend to perform a re-erase once power resume.







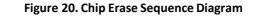
6.19. Chip Erase (CE) (60/C7H)

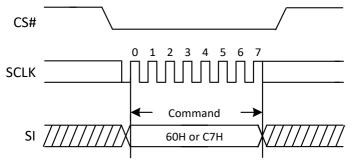
The Chip Erase (CE) command is for erasing the all data of the chip. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit .The Chip Erase (CE) command is entered by driving CS# Low, followed by the command code on Serial Data Input (SI). CS# must be driven Low for the entire duration of the sequence.

The Chip Erase command sequence: CS# goes low \rightarrow sending Chip Erase command \rightarrow CS# goes high. The command sequence is shown in Figure 20. CS# must be driven high after the eighth bit of the command code has been latch in, otherwise the Chip Erase command is not executed. As soon as CS# is driven high, the self-timed Chip Erase cycle (whose duration is tCE) is initiated. While the Chip Erase cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Chip Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. The Chip Erase (CE) command is ignored if one or more sectors are protected.

Note: Power disruption during erase operation will cause incomplete erase and data corruption, thus recommend to perform a re-erase once power resume.







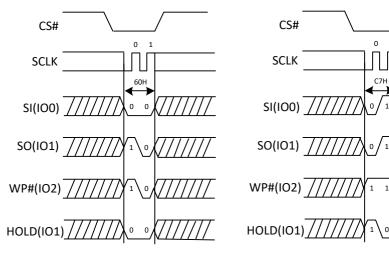


0 1 Л

C7H

0 1

1 1



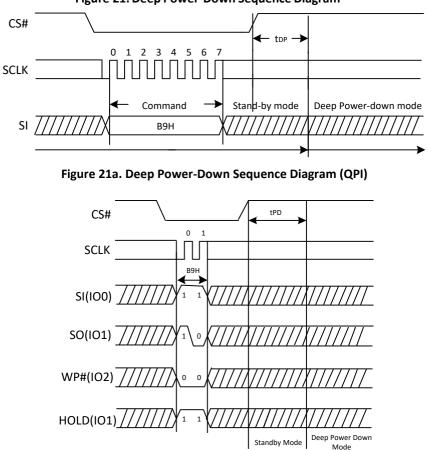


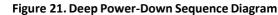
6.20. Deep Power-Down (DP) (B9H)

Executing the Deep Power-Down (DP) command is the only way to put the device in the lowest consumption mode (the Deep Power-Down Mode). It can also be used as an extra software protection mechanism, while the device is not in active use, since in this mode, the device ignores all Write, Program and Erase commands. Driving CS# high deselects the device, and puts the device in the Standby Mode (if there is no internal cycle currently in progress). But this mode is not the Deep Power-Down Mode. The Deep Power-Down Mode can only be entered by executing the Deep Power-Down (DP) command. Once the device has entered the Deep Power-Down Mode, all commands are ignored except the Release from Deep Power-Down and Read Device ID (RDI) command. This releases the device from this mode. The Release from Deep Power-Down and Read Device ID (RDI) command also allows the Device ID of the device to be output on SO.

The Deep Power-Down Mode automatically stops at Power-Down, and the device always Power-Up in the Standby Mode. The Deep Power-Down (DP) command is entered by driving CS# low, followed by the command code on SI. CS# must be driven low for the entire duration of the sequence.

The Deep Power-Down command sequence: CS# goes low \rightarrow sending Deep Power-Down command \rightarrow CS# goes high. The command sequence is shown in Figure 21. CS# must be driven high after the eighth bit of the command code has been latched in; otherwise the Deep Power-Down (DP) command is not executed. As soon as CS# is driven high, it requires a delay of tDP before the supply current is reduced to ICC2 and the Deep Power-Down Mode is entered. Any Deep Power-Down (DP) command, while an Erase, Program or Write cycle is in progress, is rejected without having any effects on the cycle that is in progress.







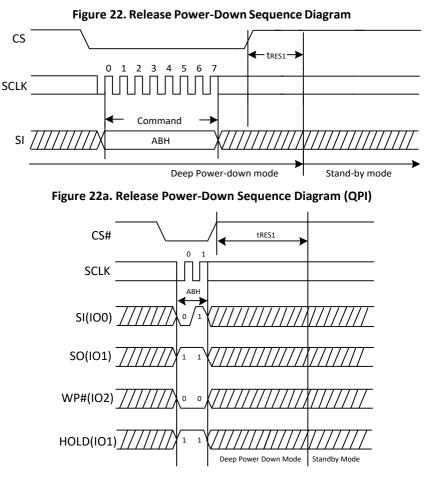
6.21. Release from Deep Power-Down and Read Device ID (RDI) (ABH)

The Release from Power-Down and Read/Device ID command is a multi-purpose command. It can be used to release the device from the Power-Down state or obtain the devices electronic identification (ID) number.

To release the device from the Power-Down state, the command is issued by driving the CS# pin low, shifting the instruction code "ABH" and driving CS# high as shown in Figure 22. Release from Power-Down will take the time duration of tRES1 (See AC Characteristics) before the device will resume normal operation and other command are accepted. The CS# pin must remain high during the tRES1 time duration.

When used only to obtain the Device ID while not in the Power-Down state, the command is initiated by driving the CS# pin low and shifting the instruction code "ABH" followed by 3-dummy byte. The Device ID bits are then shifted out on the falling edge of SCLK with most significant bit (MSB) first as shown in Figure 22b. The Device ID value for the device is listed in Manufacturer and Device Identification table. The Device ID can be read continuously. The command is completed by driving CS# high.

When used to release the device from the Power-Down state and obtain the Device ID, the command is the same as previously described, and shown in Figure 22b, except that after CS# is driven high it must remain high for a time duration of tRES2 (See AC Characteristics). After this time duration the device will resume normal operation and other command will be accepted. If the Release from Power-Down/Device ID command is issued while an Erase, Program or Write cycle is in process (when WIP equal 1) the command is ignored and will not affects on the current cycle.





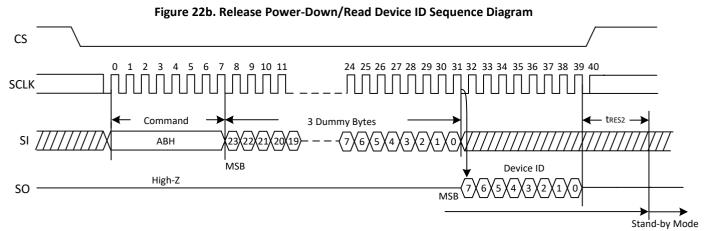
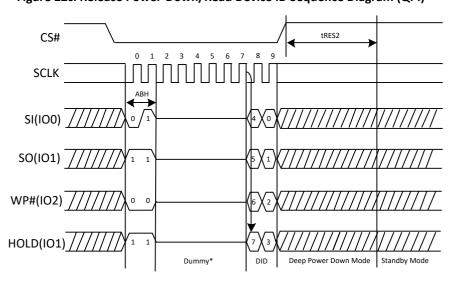


Figure 22c. Release Power-Down/Read Device ID Sequence Diagram (QPI)





6.22. Read Manufacture ID/ Device ID (REMS) (90H)

The Read Manufacturer/Device ID command is an alternative to the Release from Power-Down / Device ID command that provides both the JEDEC assigned Manufacturer ID and the specific Device ID.

The command is initiated by driving the CS# pin low and shifting the command code "90H" followed by a 24-bit address (A23-A0) of 000000H. After which, the Manufacturer ID and the Device ID are shifted out on the falling edge of SCLK with most significant bit (MSB) first is shown in Figure 23. If the 24-bit address is initially set to 000001H, the Device ID will be read first. In QPI mode the dummy cycles can be configured by COH command. When the dummy cycle is configured to 4, addr[0] input must be 0.

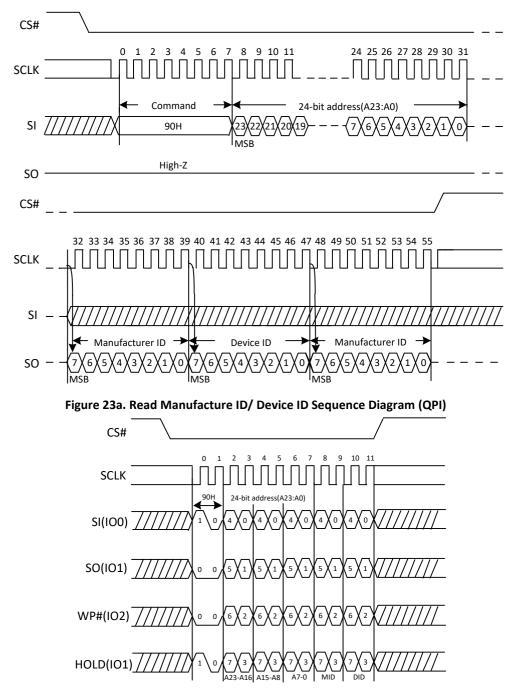


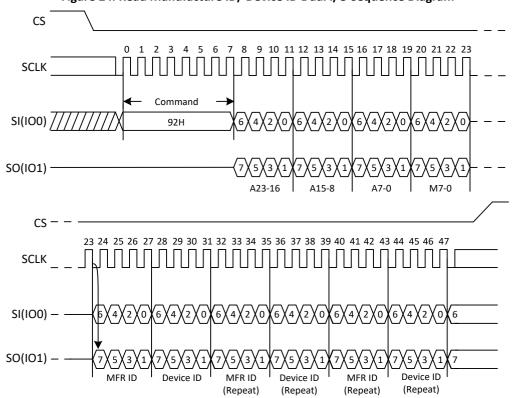
Figure 23. Read Manufacture ID/ Device ID Sequence Diagram



6.23. Read Manufacture ID/ Device ID Dual I/O (92H)

The Read Manufacturer/Device ID Dual I/O command is an alternative to the Release from Power-Down / Device ID command that provides both the JEDEC assigned Manufacturer ID and the specific Device ID by dual I/O.

The command is initiated by driving the CS# pin low and shifting the command code "92H" followed by a 24-bit address (A23-A0) of 000000H. After which, the Manufacturer ID and the Device ID are shifted out on the falling edge of SCLK with most significant bit (MSB) first as shown in Figure 24 If the 24-bit address is initially set to 000001H, the Device ID will be read first.

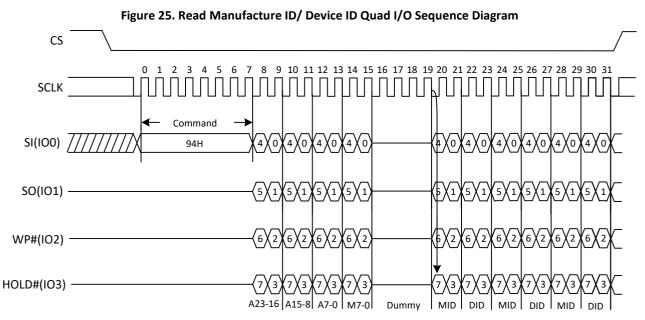






6.24. Read Manufacture ID/ Device ID Quad I/O (94H)

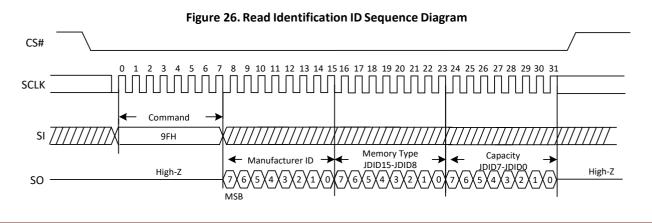
The Read Manufacturer/Device ID Quad I/O command is an alternative to the Release from Power-Down / Device ID command that provides both the JEDEC assigned Manufacturer ID and the specific Device ID by quad I/O. The command is initiated by driving the CS# pin low and shifting the command code "94H" followed by a 24-bit address (A23-A0) of 000000H. After which, the Manufacturer ID and the Device ID are shifted out on the falling edge of SCLK with most significant bit (MSB) first is shown in Figure 25. If the 24-bit address is initially set to 000001H, the Device ID will be read first.



6.25. Read Identification (RDID) (9FH)

The Read Identification (RDID) command allows the 8-bit manufacturer identification to be read, followed by two bytes of device identification. The device identification indicates the memory type in the first byte, and the memory capacity of the device in the second byte. Any Read Identification (RDID) command while an Erase or Program cycle is in progress, is not decoded, and has no effect on the cycle that is in progress. The Read Identification (RDID) command should not be issued while the device is in Deep Power-Down Mode.

The device is first selected by driving CS# to low. Then, the 8-bit command code for the command is shifted in. This is followed by the 24-bit device identification, stored in the memory, being shifted out on Serial Data Output, each bit being shifted out during the falling edge of Serial Clock. The command sequence is shown in Figure 26. The Read Identification (RDID) command is terminated by driving CS# to high at any time during data output. When CS# is driven high, the device is put in the Standby Mode. Once in the Standby Mode, the device waits to be selected, so that it can receive, decode and execute commands.



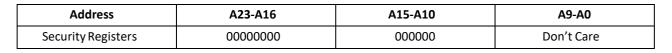


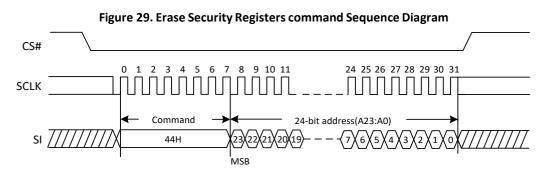
6.26. Erase Security Registers (44H)

The XT25F32B-S provides four 256-byte Security Registers which only erased all at once but able to program individually. These registers may be used by the system manufacturers to store security and other important information separately from the main memory array.

The Erase Security Registers command is similar to Sector/Block Erase command. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit.

The Erase Security Registers command sequence: CS# goes low→sending Erase Security Registers Command→CS# goes high. The command sequence is shown in Figure 29. CS# must be driven high after the eighth bit of the command code has been latched in, otherwise the Erase Security Registers command is not executed. As soon as CS# is driven high, the self-timed Erase Security Registers cycle (whose duration is tSE) is initiated. While the Erase Security Registers cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Erase Security Registers cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. The Security Registers Lock Bit (LB) in the Status Register can be used to OTP protect the security registers. Once the LB bit is set to 1, the Security Registers will be permanently locked; the Erase Security Registers command will be ignored.





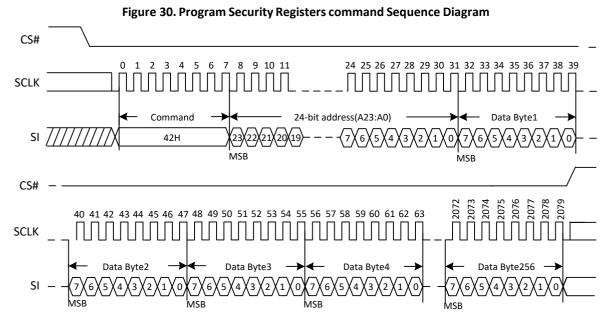
6.27. Program Security Registers (42H)

The Program Security Registers command is similar to the Page Program command. It allows from 1 to 256 bytes Security Registers data to be programmed. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit before sending the Program Security Registers command. The Program Security Registers command is entered by driving CS# Low, followed by the command code (42H), three address bytes and at least one data byte on SI. As soon as CS# is driven high, the self-timed Program Security Registers cycle (whose duration is tPP) is initiated. While the Program Security Registers cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Program Security Registers cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset.

If the Security Registers Lock Bit (LB) is set to 1, the Security Registers will be permanently locked. Program Security Registers command will be ignored.

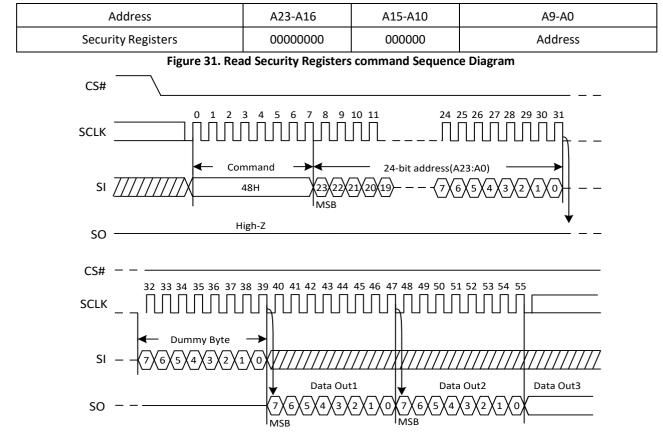
Address	A23-A16	A15-A8	A7-A0
Security Registers 0	00H	00H	Byte Address
Security Registers 1	00H	01H	Byte Address
Security Registers 2	00H	02H	Byte Address
Security Registers 3	00H	03H	Byte Address





6.28. Read Security Registers (48H)

The Read Security Registers command is similar to Fast Read command. The command is followed by a 3byte address (A23-A0) and a dummy byte, each bit being latched-in during the rising edge of SCLK. Then the memory content, at that address, is shifted out on SO, each bit being shifted out, at a Max frequency fC, during the falling edge of SCLK. The first byte addressed can be at any location. The address is automatically incremented to the next address after each byte of data is shifted out. Once the A9-A0 address reaches the last byte of the register (Byte 3FFH), it will reset to 000H, the command is completed by driving CS# high.



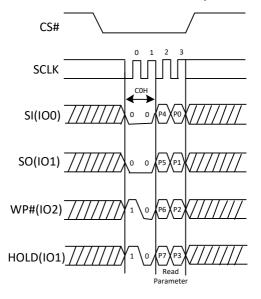


6.29. Set Read Parameters (COH)

In QPI mode the "Set Read Parameters (COH)" command can be used to configure the number of dummy clocks for "Fast Read (OBH)", "Quad I/O Fast Read (EBH)" and "Burst Read with Wrap (OCH)" command, and to configure the number of bytes of "Wrap Length" for the "Burst Read with Wrap (OCH)" command. The "Wrap Length" is set by W5-6 bit in the "Set Burst with Wrap (77H)" command. This setting will remain unchanged when the device is switched from Standard SPI mode to QPI mode.

P5-P4	Dummy Clocks	Maximum Read Freq.	P1-P0	Wrap Length
0 0	4	48MHz	0 0	8-byte
0 1	4	48MHz	01	16-byte
10	6	48MHz	10	32-byte
11	8	48MHz	11	64-byte

Figure 32. Set Read Parameters command Sequence Diagram





6.30. Burst Read with Wrap (OCH)

The "Burst Read with Wrap (0CH)" command provides an alternative way to perform the read operation with "Wrap Around" in QPI mode. This command is similar to the "Fast Read (0BH)" command in QPI mode, except the addressing of the read operation will "Wrap Around" to the beginning boundary of the "Wrap Around" once the ending boundary is reached. The "Wrap Length" and the number of dummy clocks can be configured by the "Set Read Parameters (COH)" command. When the dummy cycle is configured to 4, addr[0] input must be 0.

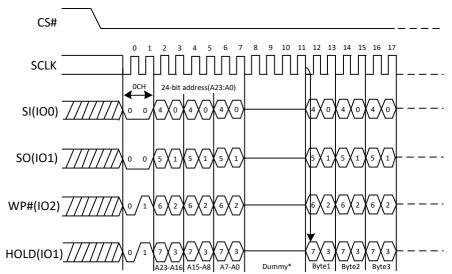
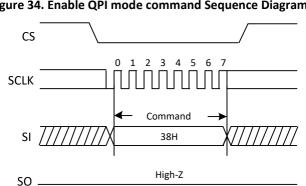
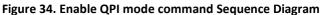


Figure 33. Burst Read with Wrap command Sequence Diagram

6.31. Enable QPI (38H)

The device support both Standard/Dual/Quad SPI and QPI mode. The "Enable QPI (38H)" command can switch the device from SPI mode to QPI mode. See the command Table 2a for all support QPI commands. In order to switch the device to QPI mode, the Quad Enable (QE) bit in Status Register-1 must be set to 1 first, and "Enable QPI (38H)" command must be issued. If the QE bit is 0, the "Enable QPI (38H)" command will be ignored and the device will remain in SPI mode. When the device is switched from SPI mode to QPI mode, the existing Write Enable Latch and the Wrap Length setting will remain unchanged.





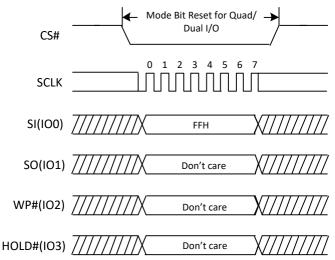


6.32. Continuous Read Mode Reset (CRMR) (FFH)/ Disable QPI (FFH)

The Dual/Quad I/O Fast Read operations, "Continuous Read Mode" bits (M7-0) are implemented to further reduce command overhead. By setting the (M7-0) to AXH, the next Dual/Quad I/O Fast Read operations do not require the BBH/EBH/E7H command code.

Because the XT25F32B-S has no hardware reset pin, so if Continuous Read Mode bits are set to "AXH", the XT25F32B-S will not recognize any standard SPI commands. So Continuous Read Mode Reset command will release the Continuous Read Mode from the "AXH" state and allow standard SPI command to be recognized. The command sequence is show in Figure 35.

Figure 35. Continuous Read Mode Reset Sequence Diagram



Disable QPI (FFH)

To exit the QPI mode and return to Standard/Dual/Quad SPI mode, the "Disable QPI (FFH)" command must be issued. When the device is switched from QPI mode to SPI mode, the existing Write Enable Latch and the Wrap Length setting will remain unchanged. When the device is in QPI mode, the first FFH command will exit continuous read mode and the second FFH command will exit QPI mode.

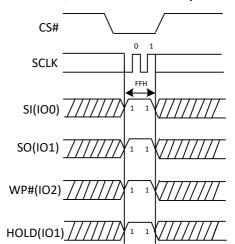


Figure 35a. Disable QPI mode command Sequence Diagram



6.33. Enable Reset (66H) and Reset (99H)

SO(IO1) //

WP#(IO2) /

HOLD(IO1)

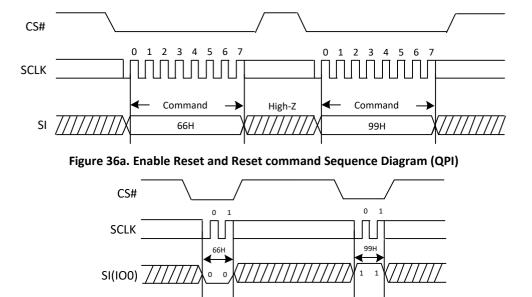
1 1

1

0

If the Reset command is accepted, any on-going internal operation will be terminated and the device will return to its default power-on state and lose all the current volatile settings, such as Volatile Status Register bits, Write Enable Latch status (WEL), Read Parameter setting (P7-P0) and Wrap Bit Setting (W6-W4).

The "Reset (99H)" command sequence as follow: CS# goes low \rightarrow Sending Enable Reset command \rightarrow CS# goes high \rightarrow CS# goes low \rightarrow Sending Reset command \rightarrow CS# goes high. Once the Reset command is accepted by the device, the device will take approximately tRST_R to reset. During this period, no command will be accepted. Data corruption may happen if there is an on-going internal Erase or Program operation when Reset command sequence is accepted by the device. It is recommended to check the BUSY bit and the SUS bit in Status Register before issuing the Reset command sequence.



0 0

0 0





6.34. Read Serial Flash Discoverable Parameter (5AH)

The Serial Flash Discoverable Parameter (SFDP) standard provides a consistent method of describing the functional and feature capabilities of serial flash devices in a standard set of internal parameter tables. These parameter tables can be interrogated by host system software to enable adjustments needed to accommodate divergent features from multiple vendors. The concept is similar to the one found in the Introduction of JEDEC Standard, JESD68 on CFI. SFDP is a standard of JEDEC Standard No.216.

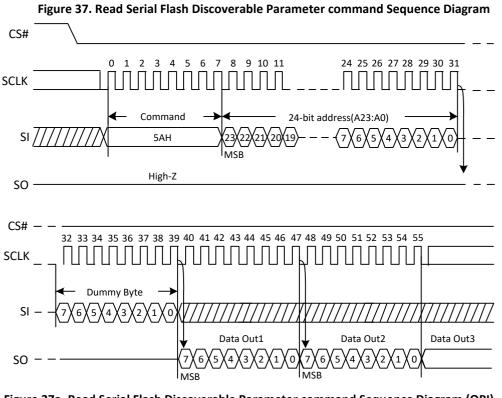
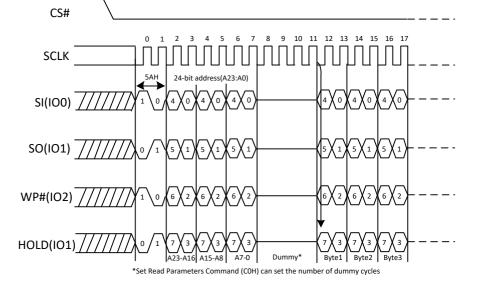


Figure 37a. Read Serial Flash Discoverable Parameter command Sequence Diagram (QPI)



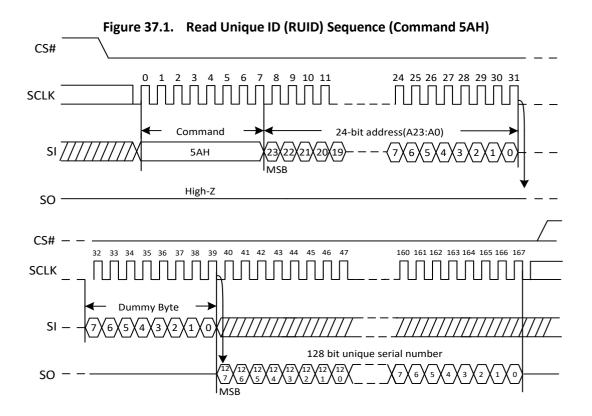


6.35. Read Unique ID (5AH)

The Read Unique ID command accesses a factory-set read-only 128bit number that is unique to each XT25F32B-S device. The Unique ID can be used in conjunction with user software methods to help prevent copying or cloning of a system.

The Read Unique ID command sequence: CS# goes low \rightarrow sending Read Unique ID command \rightarrow 00H \rightarrow 01H \rightarrow 94H \rightarrow Dummy byte \rightarrow 128bit Unique ID Out \rightarrow CS# goes high.

The command sequence is show below.





Description	Comment	Add(H)	DW Add	Data	Data
		(Byte)	(Bit)		
SFDP Signature	Fixed:50444653H	00H	07:00	53H	53H
		01H	15:08	46H	46H
		02H	23:16	44H	44H
		03H	31:24	50H	50H
SFDP Minor Revision Number	Start from 00H	04H	07:00	00H	00H
SFDP Major Revision Number	Start from 01H	05H	15:08	02H	02H
Number of Parameters Headers	Start from 00H	06H	23:16	01H	01H
Unused	Contains 0xFFH and can never be	07H	31:24	FFH	FFH
	changed				
ID number (JEDEC)	00H: It indicates a JEDEC specified	08H	07:00	00H	00H
	header				
Parameter Table Minor Revision	Start from 0x00H	09H	15:08	00H	00H
Number					
Parameter Table Major Revision	Start from 0x01H	0AH	23:16	02H	02H
Number					
Parameter Table Length	How many DWORDs in the	ОВН	31:24	09H	09H
(in double word)	Parameter table				
Parameter Table Pointer (PTP)	First address of JEDEC Flash	0CH	07:00	30H	30H
	Parameter table	0DH	15:08	00H	00H
		0EH	23:16	00H	00H
Unused	Contains 0xFFH and can never be	0FH	31:24	FFH	FFH
	changed				
ID Number	It is indicates XTX	10H	07:00	OBH	0BH
(XTX Manufacturer ID)	manufacturer ID				
Parameter Table Minor Revision	Start from 0x00H	11H	15:08	00H	00H
Number					
Parameter Table Major Revision	Start from 0x01H	12H	23:16	02H	02H
Number					
Parameter Table Length	How many DWORDs in the	13H	31:24	03H	03H
(in double word)	Parameter table				
Parameter Table Pointer (PTP)	First address of XTX Flash Parameter	14H	07:00	60H	60H
	table	15H	15:08	00H	00H
		16H	23:16	00H	00H
Unused	Contains 0xFFH and can never be	17H	31:24	FFH	FFH
	changed				



Parameter Table (1): JEDEC Flash Parameter Tables

Description	Comment	Add(H)	DW Add	Data	Data
		(Byte)	(Bit)		
	00: Reserved; 01: 4KB erase;				
Block/Sector Erase Size	10: Reserved;		01:00	01b	
	11: not support 4KB erase				
Write Granularity	0: 1Byte, 1: 64Byte or larger		02	1b	
Write Enable Instruction Request-	0: Nonvolatile status bit				
ed for Writing to Volatile	1: Volatile status bit		03	0b	
Status Registers	(BP status register bit)	ЗОН			E5H
	0: Use 50H Opcode,	5011			LJII
Write Enable Opcode Select for	1: Use 06H Opcode,				
Writing to Volatile Status Regis-	Note: If target flash status register is		04	Ob	
ters	Nonvolatile, then bits 3 and 4 must				
	be set to 00b.				
United	Contains 111b and can never be		07.05	1116	
Unused	changed		07:05	111b	
4KB Erase Opcode		31H	15:08	20H	20H
(1-1-2) Fast Read	0=Not support, 1=Support		16	1b	
Address Bytes Number used in	00: 3Byte only, 01: 3 or 4Byte,		10.17	001-	
addressing flash array	10: 4Byte only, 11: Reserved		18:17	00b	
Double Transfer Rate (DTR)	0 Net suggest 1 Suggest		10	Oh	
clocking	0=Not support, 1=Support	32H	19	0b	F1H
(1-2-2) Fast Read	0=Not support, 1=Support		20	1b	
(1-4-4) Fast Read	0=Not support, 1=Support		21	1b	
(1-1-4) Fast Read	0=Not support, 1=Support		22	1b	
Unused			23	1b	
Unused		33H	31:24	FFH	FFH
Flash Memory Density		37H:34H	31:00	01FFFFF	FH
(1-4-4) Fast Read Number of Wait	0 0000b: Wait states (Dummy				
states	Clocks) not support (M7-M0 excluded)	38H	04:00	00100b	44H
(1-4-4) Fast Read Number of Mode Bits	000b:Mode Bits not support		07:05	010b	
(1-4-4) Fast Read Opcode		39H	15:08	EBH	EBH
(1-1-4) Fast Read Number of Wait	0 0000b: Wait states (Dummy				
states	Clocks) not support		20:16	01000b	
(1-1-4) Fast Read Number of Mode Bits	000b:Mode Bits not support	— 3AH	23:21	000b	08H
(1-1-4) Fast Read Opcode		ЗВН	31:24	6BH	6BH
,					



(1-1-2) Fast Read Number of Wait states0 0000b: Wait states (Dummy clock) not supportA.H.0-4.000.0000b0.000b(1-1-2) Fast Read Number of Mode Bits000b: Mode Bits not support (M7-M0 excluded)3DH15:083BH3BH(1-2.2) Fast Read Number of Wait states000b: Wait states (Dummy (M7-M0 excluded)3EH20:1600000bb3BH(1-2.2) Fast Read Number of Mode Bits000b: Mode Bits not support (M7-M0 excluded)3FH31:24BBHBBH(1-2.2) Fast Read Opcode0=not support 1=support3FH31:24BBHBBH(2-2.2) Fast Read Opcode0=not support 1=support00:00 bit0.000 bit0.000 bit0.000 bitUnused0=not support 1=support43H:44H15:000.0FFH0.0FFHUnused0=not support43H:44H15:000.0FFH0.0FFHUnused0000b: Wait states (Dummy clock) not support32:210.000b0.0FFHUnused0000b: Wait states (Dummy clock) not support32:320.000b0.000b(2-2.2) Fast Read Number of Wait states0.000b: Wait states (Dummy clock) not support32:320.000b0.000b(2-2.2) Fast Read Number of Wait states0.000b: Wait states (Dummy clock) not support32:320.000b0.000b(2-2.2) Fast Read Number of Wait states0.000b: Wait states (Dummy clock) not support32:320.000b0.000b(2-2.2) Fast Read Number of Wait states0.0000b: Wait states (Dummy clock) not suppor	Description	Comment	Add(H) (Byte)	DW Add (Bit)	Data	Data	
(1-1-2) Fast Read Number of Mode Bits 000b: Mode Bits not support 3CH 07.05 3CH 07.05 000b 08H (1-1-2) Fast Read Opcode 0000b: Wait states (Dummy (M7-M0 excluded) 3DH 15.08 3BH 3BH (1-2-2) Fast Read Number of Mode Bits 00000b: Wait states (Dummy Clocks) not support (M7-M0 excluded) 3EH 31.24 BBH BBH BBH (1-2-2) Fast Read Number of Mode Bits 0000: Mode Bits ac Jummy clocks (M7-M0) 3FH 31.24 BBH BBH (1-2-2) Fast Read Opcode 0=not support 1=support 40H 11b 7EH 000 7EH 0.000 7EH 0.000 7EH 0.000 7EH 0.000 7EH				04:00	01000b		
	(1-1-2) Fast Read Number		3CH	07:05 000b		— 08H	
of Wait statesClocks) not support (M7-M0 excluded)3H20:16000000b40H(1-2-2) Fast Read Number Of Mode Bits100: SBN Mode Bits = 2 dummy clocks3FH31:24BBHBBH(2-2-2) Fast Read Opcode0=not support1=support40H00bbBBHBBH(2-2-2) Fast Read Opcode0=not support1=support40H00bbFH(4-4-4) Fast Read0=not support1=support40H00bbFH(4-4-4) Fast Read Number (1-2-2) Fast Read Number0=not support1=support43H:41H31:080xFFH(2-2-2) Fast Read Number (2-2-2) Fast Read Number of Mode Bits0000b: Wait states (Dummy (2-2-2) Fast Read Number (2-2-2) Fast Read Number (2-2-2) Fast Read Number of Mode Bits not support000b: Mode Bits not support00H00H(2-2-2) Fast Read Number of Mode Bits000b: Mode Bits not support46H31:24FFH9H(2-2-2) Fast Read Number of Mode Bits000D: Wait states (Dummy (Clock) not support49H:4815:000xFFI9H(2-2-2) Fast Read Opcode000D: Mode Bits not support (M7-M0) included)49H:4815:000xFFI9H9H(4-4-4) Fast Read Opcode000D: Mode Bits not support (M7-M0) included)4H31:24FFH9H9H(4-4-4) Fast Read Opcode000D: Mode Bits not support (M7-M0) included)3H4H31:24EBH9H9H9H9H9H9H9H9H9H9H9H9H <td>(1-1-2) Fast Read Opcode</td> <td></td> <td>3DH</td> <td>15:08</td> <td>3BH</td> <td>3BH</td>	(1-1-2) Fast Read Opcode		3DH	15:08	3BH	3BH	
I L D No. Hole Mathematical Mathmaterical Mathmaterical Mathmatical Mathematical Mathematical Math	. ,	Clocks) not support	3EH	20:16	000000b	40H	
1-2-2) Fast Read0=not support1=support00b(2-2-2) Fast Read0=not support1=support40H 33.01 111b(4-4-4) Fast Read0=not support1=support 0 0b 03.01 111bUnused0000b:43H:41H31.080xFFH0xFFHUnused43H:41H31.080xFFH0xFFH0xFFHUnused00000b: Wait states (Dummy clocks) not support46H 23.21 0000bof Mode Bits000b: Mode Bits not support47H31:24FFH00H(2-2-2) Fast Read Number of Mode Bits000b: Wait states (Dummy clocks) not support47H31:24FFH00H(2-2-2) Fast Read Number of Mode Bits0000b: Wait states (Dummy clocks) not support47H31:24FFH00H(4-4-4) Fast Read Number of Wait states0000b: Wait states (Dummy clocks) not support48H20:1601000b48H(4-4-4) Fast Read Number of Mode Bits not support00b: Mode Bits not support (M7-M0) included)4AH23:21010b48H(4-4-4) Fast Read Number of Mode Bits not support (M7-M0)4BH31:24EBHEBHSector Type 1 SizeSector/block size=2^N Bytes 0x0b: this sector type don't exist4CH77:000CH0CHSector Type 2 Fase OpcodeSector/block size=2^N Bytes 0x0b: this sector type don't exist5DH07:0010H10HSector Type 3 SizeSector/block size=2^N Bytes 0x0b: this sector type don't exist		010b: 8bit Mode Bits = 2 dummy clocks		23:21	010b		
Unused Image: Constraint of the sector	(1-2-2) Fast Read Opcode		3FH	31:24	BBH	BBH	
(4-4-4) Fast Read 0=not support 1=support 40H 004 1b Unused 0 0.000 3111b 0.07.05 111b Unused 43H.41H 31.08 0.07.0FH 0.07.0F 0.07.0FH </td <td>(2-2-2) Fast Read</td> <td>0=not support 1=support</td> <td></td> <td>00</td> <td>0b</td> <td></td>	(2-2-2) Fast Read	0=not support 1=support		00	0b		
(4-4-4) Fast Read 0=not support 1=support 04 1b Unused I 07:05 111b Unused I 43H:41H 31:08 0xFFH Unused 0000b: Wait states (Dummy 45H:44H 15:00 0xFFH Unused 0000b: Wait states (Dummy 46H 15:00 0xFFH (2-2-2) Fast Read Number 000b: Mode Bits not support 46H 23:21 0000b 0000b of Mode Bits 000b: Wait states (Dummy 47H 31:24 FFH FFH (4-4-4) Fast Read Number of Wait 0000b: Wait states (Dummy 49H:48H 15:00 0xFFH (4-4-4) Fast Read Number of Wait 0000b: Wait states (Dummy 49H:48H 15:00 01000b (4-4-4) Fast Read Number of Wait 0000b: Wait states (Dummy 44H 31:24 FFH 0xFFH (4-4-4) Fast Read Number of Wait 0000b: Wait states (Dummy 44H 31:24 EBH 62H (4-4-4) Fast Read Number of Wait Sector/block size=2^N Ngtes 0xOH: his sector type don'r exist 70:00 0CH	Unused			03:01	111b		
Unused131:080xFFH0xFFHUnused0000b: Wait states (Dummy Clocks) not support45H:44H15:000xFFH0xFFH(2-2-2) Fast Read Number of Mode Bits0000b: Wait states (Dummy Clocks) not support $A6H$ $23:21$ 000b $000b$ (2-2-2) Fast Read Opcode000b: Mode Bits not support47H31:24FFHFFHUnused47H31:24FFHFFH $000b$ $0xFFH$ $0xFFH$ Unused0000b: Wait states (Dummy Clocks) not support47H31:24FFH FFH Unused0000b: Wait states (Dummy Clocks) not support $49H:48H$ 15:00 $0xFFH$ $0xFFH$ (4-4-4) Fast Read Number of Wait states0000b: Wait states (Dummy Clocks) not support $20:16$ $01000b$ $0xFFH$ (4-4-4) Fast Read Number of Mode Bits000b: Mode Bits not support O10b: Mode Bits are 2 dummy clocks $20:16$ $01000b$ $0xFFH$ (4-4-4) Fast Read Opcode4BH31:24EBHEBHSector Type 1 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $4CH$ $07:00$ $0CH$ $0CH$ Sector Type 2 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $4EH$ $31:24$ $52H$ $52H$ $23:16$ $0OH$ Sector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $50H$ $07:00$ $10H$ $10H$ Sector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $51H$ $15:08$ 0	(4-4-4) Fast Read	0=not support 1=support	40H	04	1b	FEH	
UnusedImage: Constraint of the sector type 4 SizeImage: Constraint of the sector type 4 Size45H:44H15:000xFFH0xFFH $(2-2)$ Fast Read Number of Wait states0 0000b: Wait states (Dummy Clocks) not support $20:16$ 00000b0000b $(2-2)$ Fast Read Number of Mode Bits000b: Mode Bits not support $46H$ $23:21$ 000b00H $(2-2-2)$ Fast Read Opcode47H $31:24$ FFHFFHUnused49H:48H15:000xFFH0xFFH $(4-4-4)$ Fast Read Number of Wait states0000b: Wait states (Dummy Clocks) not support (MY-M0 included) $4H$ $20:16$ $01000b$ $(4-4-4)$ Fast Read Number of Mode Bits0000b: Mode Bits not support 010b: Boit Mode Bits on t support 010b: Boit Mode Bits not support 010b: Boit Mode Bits a 2 dummy clocks 0x00b: this sector type don't exist $4H$ $20:16$ $01000b$ $(4-4-4)$ Fast Read Opcode4BH $31:24$ EBHEBHSector Type 1 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $4CH$ $07:00$ $0CH$ $0CH$ Sector Type 2 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $50H$ $07:00$ $10H$ $10H$ Sector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $50H$ $07:00$ $10H$ $10H$ Sector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $50H$ $07:00$ $10H$ $10H$	Unused			07:05	111b		
(2-2-2) Fast Read Number of Wait states0 0000b: Wait states (Dummy Clocks) not support20:1600000b00000b(2-2-2) Fast Read Number of Mode Bits000b: Mode Bits not support23:21000b000b(2-2-2) Fast Read Opcode477H31:24FFHFFHUnused49H:48H15:000xFFH0xFFH(4-4-4) Fast Read Number of Wait states0000b: Wait states (Dummy Clocks) not support Clocks) not support Olob: Mode Bits not support Olob: Mode Bits not support Olob: Mode Bits not support (M7-M0 included)4HH15:000xFFH(4-4-4) Fast Read Number of Mode Bits0000b: Wait states (Dummy Clocks) not support Olob: Bits Mode Bits not support Olob: Bit Mode Bits not support Olob: Bits mode Bits not support Olob: Bits mode Bits not support Olob: Bit Mode	Unused		43H:41H	31:08	0xFFH	0xFFH	
of Wait statesClocks) not support $20:16$ $00000b$ $(2-2.2)$ Fast Read Number of Mode Bits $000b:$ Mode Bits not support $46H$ $23:21$ $000b$ $(2-2.2)$ Fast Read Opcode47H $31:24$ FFHFFHUnused49H:48H15:00 $0xFFH$ $0xFFH$ $(4-4.4)$ Fast Read Number of Wait states $0000b:$ Wait states (Dummy Clocks) not support $(M7-M0$ included) $49H:48H$ 15:00 $0xFFH$ $(4-4.4)$ Fast Read Number of Mode Bits $0000b:$ Wait states (Dummy Clocks) not support $010b:$ 8bit Mode Bits are 2 dummy clocks $20:16$ $01000b$ $0xFFH$ $(4-4.4)$ Fast Read Number of Mode Bits $0000b:$ Wait states (Dummy Clocks) not support $010b:$ 8bit Mode Bits are 2 dummy clocks $20:16$ $01000b$ $0xFFH$ $(4-4.4)$ Fast Read Opcode $0000b:$ Mode Bits are 2 dummy clocks $(M7-M0)$ $4BH$ $31:24$ EBHEBHSector Type 1 SizeSector/block size=2^N Bytes $0x00b:$ this sector type don't exist $4CH$ $07:00$ $0CH$ $0CH$ Sector Type 2 SizeSector/block size=2^N Bytes $0x00b:$ this sector type don't exist $4EH$ $31:24$ $52H$ $52H$ Sector Type 3 SizeSector/block size=2^N Bytes $0x00b:$ this sector type don't exist $50H$ $07:00$ $10H$ $10H$ Sector Type 3 SizeSector/block size=2^N Bytes $0x00b:$ this sector type don't exist $50H$ $15:08$ $D8H$ $D8H$ Sector Type 3 SizeSector/block size=2^N Bytes $0x00b:$ this sector type don't exist $52H$ $23:16$ 00	Unused		45H:44H	15:00	0xFFH	0xFFH	
(2-2-2) Fast Read Number of Mode Bits000b: Mode Bits not support46H23:21000b(2-2-2) Fast Read Opcode0000b: Wait states (Dummy Clocks) not support (M7-M0 included)47H31:24FFHFFH(4-4-4) Fast Read Number of Mode Bits0 0000b: Wait states (Dummy Clocks) not support (M7-M0 included)49H:48H15:000xFFH0xFFH(4-4-4) Fast Read Number of Mode Bits0 0000b: Wait states (Dummy Clocks) not support (IM7-M0 included)44H20:1601000b48H(4-4-4) Fast Read Number of Mode Bits0 00b: Mode Bits not support 010b: Bit Mode Bits s = 2 dummy clocks (M7-M0)44H31:24EBHEBHSector Type 1 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist4CH07:000CH0CHSector Type 2 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist4EH31:2452H52HSector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist52H23:1600H00H		. ,		20:16	00000b		
Unused49H:48H15:00 $0xFFH$ $0xFFH$ $(4-4-4)$ Fast Read Number of Wait states00000b: Wait states (Dummy Clocks) not support (M7-M0 included) $4AH$ $20:16$ $01000b$ $4BH$ $(4-4-4)$ Fast Read Number of Mode Bits000b: Mode Bits not support 010b: Bbit Mode Bits = 2 dummy clocks (M7-M0) $4AH$ $23:21$ $010b$ $4BH$ $(4-4-4)$ Fast Read Opcode4BH $31:24$ EBHEBHSector Type 1 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $4CH$ $07:00$ $0CH$ $0CH$ Sector Type 2 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $4EH$ $23:16$ $0FH$ $0FH$ Sector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $5OH$ $07:00$ $0CH$ $0FH$ Sector Type 3 FizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $3DH$ $15:08$ $D8H$ $10H$ Sector Type 3 FizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $5OH$ $07:00$ $10H$ $10H$ Sector Type 3 FizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $5OH$ $15:08$ $D8H$ $D8H$ Sector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist $52H$ $23:16$ $00H$ $00H$	(2-2-2) Fast Read Number		46H	23:21	000b	00H	
(4-4-4) Fast Read Number of Wait states0 0000b: Wait states (Dummy Clocks) not support (M7-M0 included)20:1601000b48H(4-4-4) Fast Read Number of Mode Bits000b: Mode Bits not support 010b: 8bit Mode Bits = 2 dummy clocks $(M7-M0)$ 23:21010b23:21010b(4-4-4) Fast Read Opcode4BH31:24EBHEBHSector Type 1 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist4CH07:000CH0CHSector Type 2 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist4EH23:160FH0FHSector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist51H15:08D8HD8HSector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist52H23:1600H00H	(2-2-2) Fast Read Opcode		47H	31:24	FFH	FFH	
Clocks) not support (M7-M0 included)Clocks) not support (M7-M0 included)AHH20:160100b48H(4-4-4) Fast Read Number of Mode Bits000b: Mode Bits not support 010b: 8bit Mode Bits = 2 dummy clocks23:21010b010b(4-4-4) Fast Read Opcode4BH31:24EBHEBHSector Type 1 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist4CH07:000CH0CHSector Type 2 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist4EH23:160FH0FHSector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist51H15:08D8HD8HSector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist52H23:1600H00H	Unused		49H:48H	15:00	0xFFH	0xFFH	
O1 Db: 8bit Mode Bits23:21010bof Mode Bits010b: 8bit Mode Bits = 2 dummy clocks (M7-M0)4BH31:24EBH(4-4-4) Fast Read Opcode4BH31:24EBHEBHSector Type 1 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist4CH07:000CH0CHSector Type 1 erase Opcode4DH15:0820H20HSector Type 2 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist4EH23:160FH0FHSector Type 2 erase OpcodeSector/block size=2^N Bytes 0x00b: this sector type don't exist4FH31:2452H52HSector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 erase OpcodeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 erase OpcodeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist52H23:1600H00H		Clocks) not support	4AH	20:16	01000b	48H	
Sector Type 1 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist4CH07:000CH0CHSector Type 1 erase Opcode4DH15:0820H20HSector Type 2 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist4EH23:160FH0FHSector Type 2 erase OpcodeSector/block size=2^N Bytes 0x00b: this sector type don't exist4FH31:2452H52HSector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 erase OpcodeSector/block size=2^N Bytes 0x00b: this sector type don't exist51H15:08D8HD8HSector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist52H23:1600H00H		010b: 8bit Mode Bits = 2 dummy clocks		23:21	010b		
Sector Type 1 SizeACH07:000CH0CHSector Type 1 erase Opcode4DH15:0820H20HSector Type 2 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist4EH23:160FH0FHSector Type 2 erase Opcode4FH31:2452H52HSector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 erase Opcode51H15:08D8HD8HSector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist51H15:08D8HD8H	(4-4-4) Fast Read Opcode		4BH	31:24	EBH	EBH	
Sector Type 2 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist4EH23:160FH0FHSector Type 2 erase Opcode4FH31:2452H52HSector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 erase Opcode51H15:08D8HD8HSector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist52H52H00H	Sector Type 1 Size		4CH	07:00	0CH	ОСН	
Sector Type 2 SizeAEH23:16OFHOFHSector Type 2 erase Opcode4FH31:2452H52HSector Type 3 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 erase Opcode51H15:08D8HD8HSector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist52H23:1600H00H	Sector Type 1 erase Opcode		4DH	15:08	20H	20H	
Sector Type 3 Size Sector/block size=2^N Bytes 0x00b: this sector type don't exist 50H 07:00 10H 10H Sector Type 3 erase Opcode 51H 15:08 D8H D8H Sector Type 4 Size Sector/block size=2^N Bytes 0x00b: this sector type don't exist 52H 23:16 00H 00H	Sector Type 2 Size		4EH	23:16	OFH	OFH	
Sector Type 3 Size0x00b: this sector type don't exist50H07:0010H10HSector Type 3 erase Opcode51H15:08D8HD8HSector Type 4 SizeSector/block size=2^N Bytes 0x00b: this sector type don't exist52H23:1600H00H	Sector Type 2 erase Opcode		4FH	31:24	52H	52H	
Sector/block size=2^N Bytes 52H 23:16 00H 00H	Sector Type 3 Size		50H	07:00	10H	10H	
Sector Type 4 Size 0x00b: this sector type don't exist 52H 23:16 00H 00H	Sector Type 3 erase Opcode		51H	15:08	D8H	D8H	
	Sector Type 4 Size		52H	23:16	00H	00H	
Sector Type 4 erase Opcode53H31:24FFHFFH	Sector Type 4 erase Opcode		53H	31:24	FFH	FFH	



Parameter Table (2): XTX Flash Parameter Tables

Description	Comment	Add(H) (Byte)	DW Add (Bit)	Data	Data
Vcc Supply Maximum Voltage	2000H=2.000V 2700H=2.700V 3600H=3.600V	61H:60H	15:00	3600H	3600H
Vcc Supply Minimum Voltage	1650H=1.650V 2250H=2.250V 2350H=2.350V 2700H=2.700V	63H:62H	31:16	2700H	2700H
HW Reset# pin	0=not support 1=support		00	Ob	
HW Hold# pin	0=not support 1=support	_	01	1b	
Deep Power Down Mode	0=not support 1=support	_	02	1b	
SW Reset	0=not support 1=support	_	03	1b	
SW Reset Opcode	Should be issue Reset Enable(66H) before Reset cmd.	65H:64H	11:04	1001 1001b (99H)	С99ЕН
Program Suspend/Resume	0=not support 1=support	_	12	0b	
Erase Suspend/Resume	0=not support 1=support		13	Ob	
Unused			14	1b	
Wrap-Around Read mode	0=not support 1=support	_	15	1b	
Wrap-Around Read mode Opcode		66H	23:16	FFH	FFH
Wrap-Around Read data length	08H:support 8B wrap-around read 16H:8B&16B 32H:8B&16B&32B 64H:8B&16B&32B&64B	67H	31:24	64H	64H
Individual block lock	0=not support 1=support		00	Ob	
Individual block lock bit (Volatile/Nonvolatile)	0=Volatile 1=Nonvolatile	_	01	Ob	
Individual block lock Opcode			09:02	FFH	
Individual block lock Volatile protect bit default protect status	0=protect 1=unprotect	6BH:68H	10	Ob	EBFCH
Secured OTP	0=not support 1=support		11	1b	
Read Lock	0=not support 1=support		12	Ob	
Permanent Lock	0=not support 1=support		13	1b	
Unused			15:14	11b]
Unused			31:16	FFFFH	FFFFH



7. ELECTRICAL CHARACTERISTICS

7.1. Power-on Timing

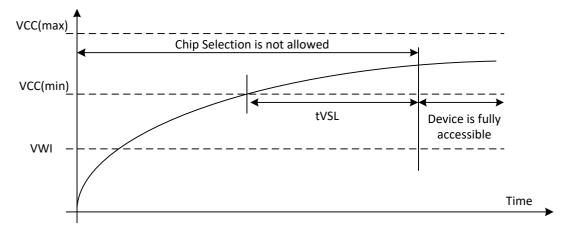


Table3. Power-Up Timing and Write Inhibit Threshold

Note: At power-down, need to ensure VCC drop to 0.5V before the next power-on in order for the device to have a proper power-on reset.

Symbol	Parameter	Min	Max	Unit
t _{vsL}	VCC(min) To CS# Low	10		us
V _{wi}	Write Inhibit Voltage	1.5	2.5	V

7.2. Initial Delivery State

The device is delivered with the memory array erased: all bits are set to 1(each byte contains FFH). The Status Register contains 00H (all Status Register bits are 0).

7.3. Data Retention and Endurance

Parameter	Typical	Unit
Data Retention Time	20	Years
Erase/Program Endurance	100K	Cycles

7.4. Latch up Characteristics

Parameter	Min	Max
Input Voltage Respect To VSS On I/O Pins	-1.0V	VCC+1.0V
VCC Current	-100mA	100mA



7.5. Absolute Maximum Ratings

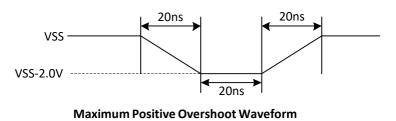
Parameter	Value	Unit
Ambient Operating Temperature	-40 to 85	°C
StorageTemperature	-65 to 150	°C
Output Short Circuit Current	200	mA
Applied Input/Output Voltage	-0.5 to 4.0	V
VCC	-0.5 to 4.0	V

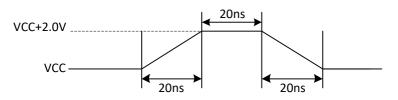
7.6. Capacitance Measurement Condition

Symbol	Parameter	Min	Тур	Max	Unit	Conditions
CIN	Input Capacitance			6	pF	VIN=0V
COUT	Output Capacitance			8	pF	VOUT=0V
CL	Load Capacitance		30		pF	
	Input Rise And Fall time			5	ns	
	Input Pulse Voltage	0.1	VCC to 0.8	VCC	V	
	Input Timing Reference Voltage	0.2	VCC to 0.7	VCC	V	
	Output Timing Reference Voltage		0.5VCC		V	

Figure 38. Input Test Waveform and Measurement Level

Maximum Negative Overshoot Waveform





Sep/18/2020



7.7. DC Characteristics

(T=-40°C~85°C,VCC=2.7~3.6V)

Symbol	Parameter	Test Condition	Min.	Тур	Max.	Unit
ILI	Input Leakage Current ⁽¹⁾				±2	μΑ
ILO	Output Leakage Current ⁽¹⁾				±2	μA
ICC1	Standby Current	CS#=VCC				
001		VIN=VCC or VSS		12	40	μA
ICC2	Deep Power-Down Current	CS#=VCC				
		VIN=VCC or VSS		0.1	4	μΑ
		CLK=0.1VCC/0.9VCC at				
		108MHz, Q=Open(*1,*2		15	20	mA
	Operating Current(Read) ⁽²⁾	I/O)				
		CLK=0.1VCC/0.9VCC at				
ICC3		80MHz, Q=Open(*1,*2,*4		13	18	mA
		I/O)				
		CLK=0.1VCC/0.9VCC at				
		50MHZ,Q=Open(*1,*2,*4		7	10	mA
		I/O)				
ICC4	Operating Current(PP)	CS#=VCC			30	mA
ICC5	Operating Current(WRSR)	CS#=VCC			30	mA
ICC6	Operating Current(SE)	CS#=VCC			30	mA
ICC7	Operating Current(BE)	CS#=VCC			30	mA
VIL	Input Low Voltage		-0.5		0.2VCC	V
VIH	Input High Voltage		0.7VCC		VCC+0.4	V
VOL	Output Low Voltage	IOL=1.6mA			0.4	V
Vон	Output High Voltage	IOH=-100uA	VCC-0.2			V

Notes:

1. Tested on sample basis and specified through design and characterization data. TA = 25° C, VCC = 3.3V.

2. Pattern 00 FF.



7.8. AC Characteristics

(T=-40°℃~85°℃,VCC=2.7~3.6V, C_L=30pF)

Symbol	Parameter	Min.	Тур.	Max.	Unit
fC	Serial Clock Frequency For: Fast Read (OBH), Dual Output(3BH)			108	MHz
fC1	Serial Clock Frequency For: Dual I/O (BBH), Quad I/O(EBH),Quad Output(6BH)			86	MHz
fC2	Serial Clock Frequency For QPI (0BH, EBH)			72	MHz
fR	Serial Clock Frequency For: Read Data(03H), Read Device ID(9FH),Read Manufacture ID (90H)			72	MHz
tCLH	Serial Clock High Time	45% PC			ns
tCLL	Serial Clock Low Time	45% PC			ns
tCLCH	Serial Clock Rise Time(Slew Rate)	0.2			V/ns
tCHCL	Serial Clock Fall Time(Slew Rate)	0.2			V/ns
tSLCH	CS# Active Setup Time	5			ns
tCHSH	CS# Active Hold Time	5			ns
tSHCH	CS# Not Active Setup Time	5			ns
tCHSL	CS# Not Active Hold Time	5			ns
tSHSL	CS# High Time (read/write)	20			ns
tSHQZ	Output Disable Time			6	ns
tCLQX	Output Hold Time	1			ns
tDVCH	Data In Setup Time	2			ns
tCHDX	Data In Hold Time	2			ns
tHLCH	Hold# Low Setup Time(relative to Clock)	5			ns
tHHCH	Hold# High Setup Time(relative to Clock)	5			ns
tCHHL	Hold# High Hold Time(relative to Clock)	5			ns
tCHHH	Hold# Low Hold Time(relative to Clock)	5			ns
tCLQV	Clock Low To Output Valid			6.5	ns
tWHSL	Write Protect Setup Time Before CS# Low	20			ns
tSHWL	Write Protect Hold Time After CS# High	100			ns
tDP	CS# High To Deep Power-Down Mode			0.1	μs
tRES1	CS# High To Standby Mode Without Electronic Signa- ture Read			20	μs
tRES2	CS# High To Standby Mode With Electronic Signature Read			20	μs
tRST_R	CS# High To Next Command After Reset (from read)			20	μs
tRST_P	CS# High To Next Command After Reset (from pro- gram)			20	μs
tRST_E	CS# High To Next Command After Reset (from erase)			12	ms
tW	Write Status Register Cycle Time		50	800	ms
tPP	Page Programming Time		0.35	0.7	ms
tSE	Sector Erase Time		70	800	ms



tBE1	Block Erase Time(32K Bytes)	0.15	1.2	S
tBE2	Block Erase Time(64K Bytes)	0.25	1.6	S
tCE	Chip Erase Time	10	30	S

- 1. Clock high or Clock low must be more than or equal to 45%Pc. Pc=1/fC(MAX)
- 2. Maximum Serial Clock Frequencies are measured results picked at the falling edge.
- 3. Typical values given for TA=25°C. Value guaranteed by design and/or characterization, are not 100% tested in production.



Figure 39. Serial Input Timing

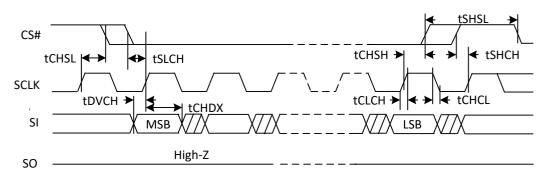
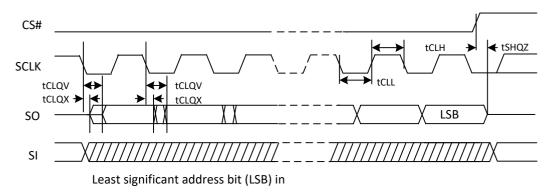


Figure 40. Output Timing



CS# CS# SCLK SO HOLD# Figure 41. Hold Timing CS# CS# CHHL tCHHL tHLCH tCHHL tHLQZ tCHHL tHLQZ tCHHL tHLQZ tCHHL tHLQZ tCHHL tHLQZ tHLQZ tCHHL tHLQZ tHLQZ tCHHL tHLQZ tCHHL tHLQZ tCHHL tHLQZ tHLQZ

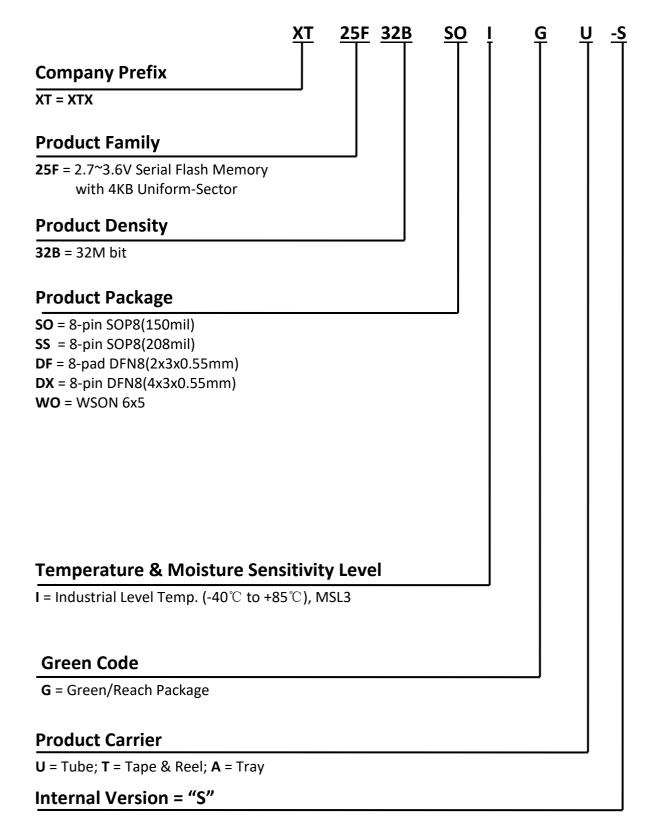
NOTE:

Standard bulk shipment is in Tube. Any alternation of packing method (for Tape, Reel and Tray etc.), please advise in advance.



8. ORDERING INFORMATION

The ordering part number is formed by a valid combination of the following

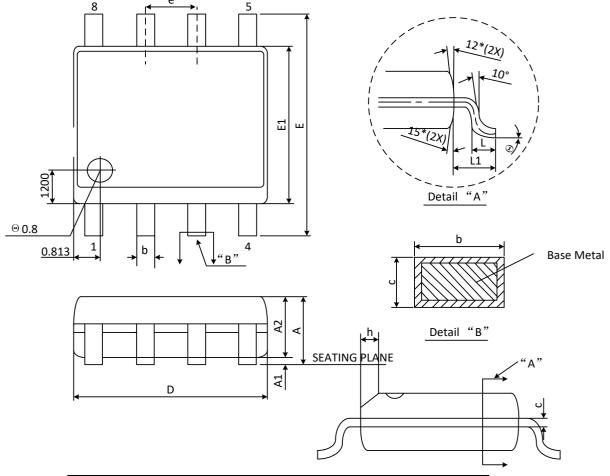




9. PACKAGE INFORMATION

9.1. Package SOP8 150MIL

e

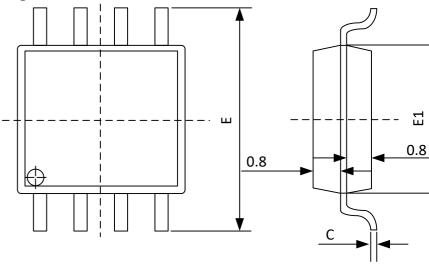


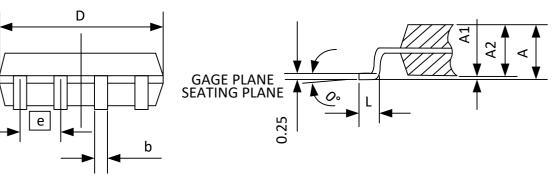
Symbol	Dimensions in Millimeters									
	Min	Norm	Max							
Α	1.350		1.750							
A1	0.100		0.250							
A2	1.300		1.500							
b	0.330		0.510							
С	0.190		0.250							
D	4.700	4.900	5.000							
E1	3.800	3.900	4.000							
е		1.270								
E	5.800	6.000	6.200							
h	0.2500	0.350	0.500							
L	0.508	0.635	0.762							
L1	0.837	1.040	1.243							
θ	0°		8°							

- 1. Coplanarity: 0.1mm
- 2. Max allowable mold flash is 0.15mm at the package ends. 0.25mm between leads.
- 3. All dimensions follow JEDEC MS-012 standard.







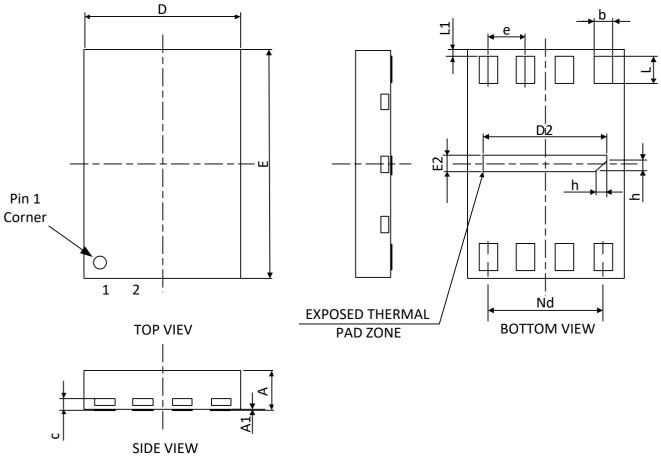


	Dimensions in Millimeters							
Symbol	Min	Norm	Max					
A	1.750	1.950	2.160					
A1	0.050	0.150	0.250					
A2	1.700	1.800	1.910					
b	0.350	0.420	0.480					
С	0.190	0.20	0.250					
D	5.130	5.230	5.330					
E	7.700	7.900	8.100					
E1	5.180	5.280	5.380					
e		1.270 BSC						
L	0.500	0.650	0.800					
θ	0°	8°						

- 1. JEDEC Outline : N/A
- 2. Coplanarity: 0.1mm
- 3. Max allowable mold flash is 0.15mm at the package ends. 0.25mm between leads.



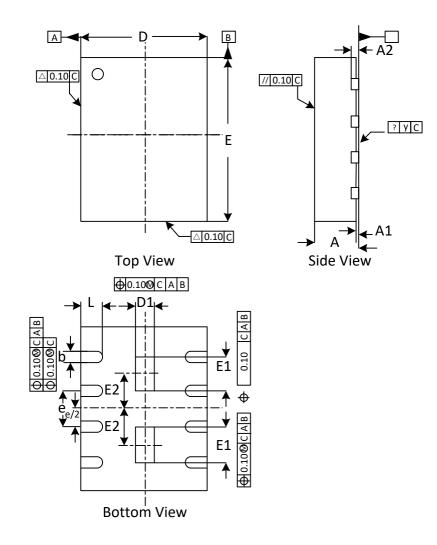




SYMBOL	MILLIMETER							
STIVIBOL	MIN	NOM	MAX					
Α	0.50	0.55	0.60					
A1	0	0.02	0.05					
b	0.18	0.25	0.30					
С	0.10	0.15	0.20					
D	1.90	2.00	2.10					
D2	1.50 1.60		1.70					
е		0.50BSC						
Nd		1.50BSC						
E	2.90	3.00	3.10					
E2	0.10	0.20	0.30					
L	0.30	0.35	0.40					
L1	0.05	0.10	0.15					
h	0.05	0.15	0.25					



9.4. Package DFN8 (4x3x0.55) mm



Sym	bol												
Un	it	Α	A1	A2	b	D	D1	Е	E1	E2	е	У	L
	Min	0.50	0.00		0.25	2.90	0.10	3.90	0.70			0.00	0.50
	Norm	0.55		0.15	0.30	3.00	0.25	4.00	0.80	0.80BSC	0.80BSC		0.60
mete	Max	0.60	0.05		0.35	3.10	0.40	4.10	0.90			0.08	0.70

- 1. Both package length and width do not include mold flash.
- The exposed metal pad area on the bottom of the package is connected to device ground (GND pin), so both Floating and connecting GND of exposed pad are also available.



10. REVISION HISTORY

Revision	Description	Date		
1.0	Initial version	Jan-25-2019		
1.1	Updated 7.1 Power-on Timing figure and description	Sep-18-2019		
	Updated to delete high temperature OPNs and changed operation current to 30mA. Changed maximum sector erase time and write security register time and typical page program time based on actual test result			
	DPD maximum change from 0.2uA to 4uA.			
1.2	Standby maximum changed from 20uA to 40uA.	Mar-30-2020		
	Read Current at 50Mhz changed from 5/7mA to 7/10mA			
	Deleted tHLQZ, tHHQX, and updated description of Hold in Device Opera- tion.			
	Updated 32K/64K tBE max to 1.2/1.6s			
	Updated QPI diagrams style			
1.3	Deleted DFN8 2x3x0.4mm Package	Sep-18-2020		
	Updated SFDP Table mistakes of DW Add 37H:34H, 3EH:4AH, 61H:68H			